EEPROM PROGRAMMABLE 2.5V PROGRAMMABLE SKEW PLL DIFFERENTIAL CLOCK DRIVER

IDT5T9891

FEATURES:

- **2.5 V$_{DD}$**
- **6 pairs of programmable skew outputs**
- **Low skew: 100ps all outputs at same interface level, 250ps all outputs at different interface levels**
- **Selectable positive or negative edge synchronization**
- **Tolerant of spread spectrum input clock**
- **Synchronous output enable**
- **Selectable inputs**
- **Input frequency: 4.17MHz to 250MHz**
- **Output frequency: 12.5MHz to 250MHz**
- **Internal non-volatile EEPROM**
- **JTAG or I²C bus serial interface for programming**
- **Hot insertable and over-voltage tolerant inputs**
- **Feedback divide selection with multiply ratios of (1-6, 8, 10, 12)**
- **Selectable HSTL, eHSTL, 1.8V/2.5V LVTTL, or LVEPECL input interface**
- **Selectable HSTL, eHSTL, or 1.8V/2.5V LVTTL output interface for each output bank**
- **Selectable differential or single-ended inputs and six differential outputs**
- **PLL bypass for DC testing**
- **External differential feedback, internal loop filter**
- **Low Jitter: <75ps cycle-to-cycle, all outputs at same interface level: <100ps cycle-to-cycle all outputs at different interface levels**
- **Power-down mode**
- **Lock indicator**
- **Available in VFQFPN package**

DESCRIPTION:

The IDT5T9891 is a 2.5V PLL differential clock driver intended for high performance computing and data-communications applications. A key feature of the programmable skew is the ability of outputs to lead or lag the REF input signal. The IDT5T9891 has six differential programmable skew outputs in six banks, including a dedicated differential feedback through the use of JTAG or I²C programming. The redundant input capability allows for a smooth change over to a secondary clock source when the primary clock source is absent.
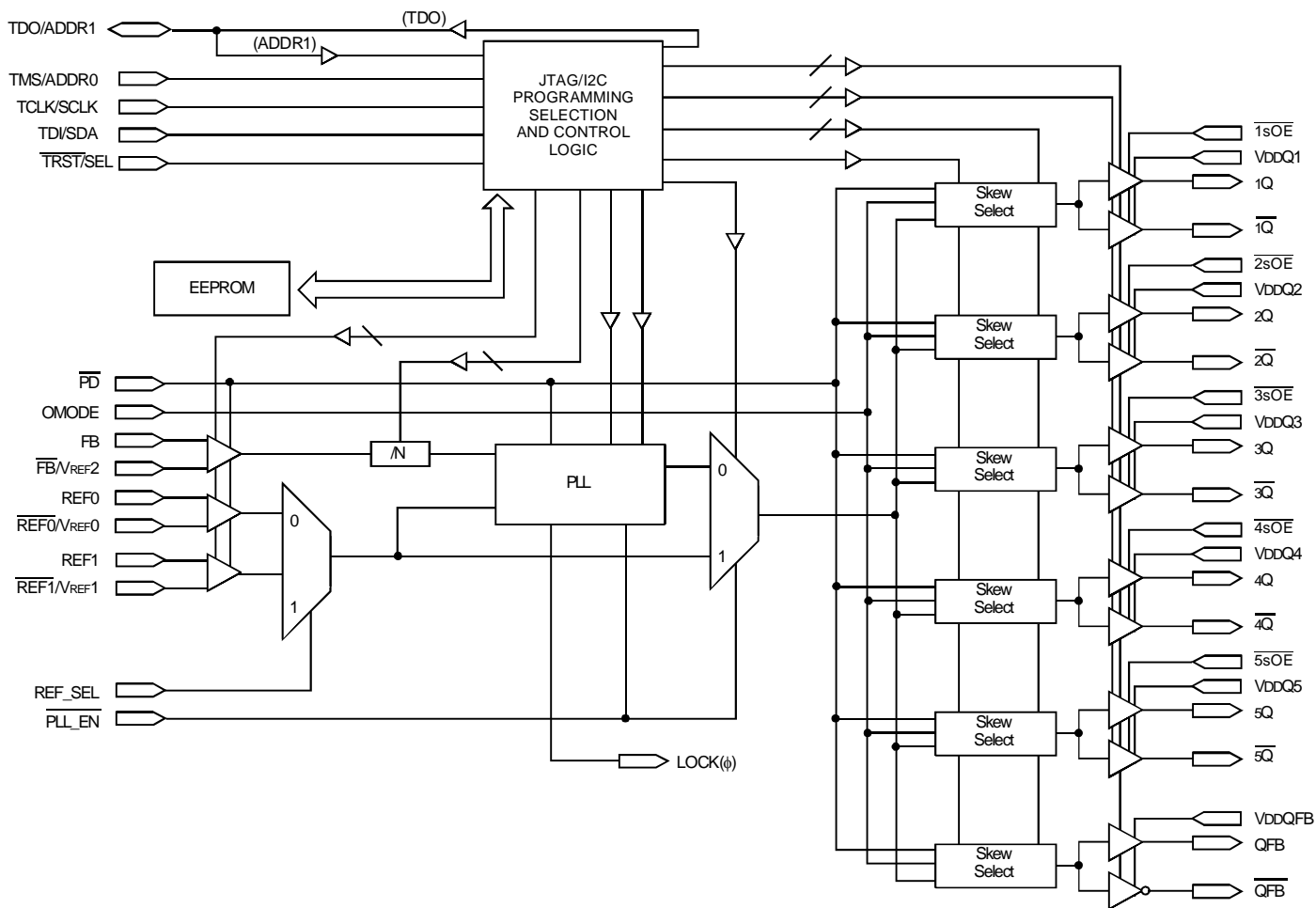
The clock driver can be configured through the use of JTAG/I²C programming. An internal EEPROM will allow the user to save and restore the configuration of the device.

The feedback bank allows divide-by-functionality from 1 to 12 through the use of JTAG or I²C programming. This provides the user with frequency multiplication 1 to 12 without using divided outputs for feedback. Each output bank also allows for a divide-by functionality of 2 or 4.
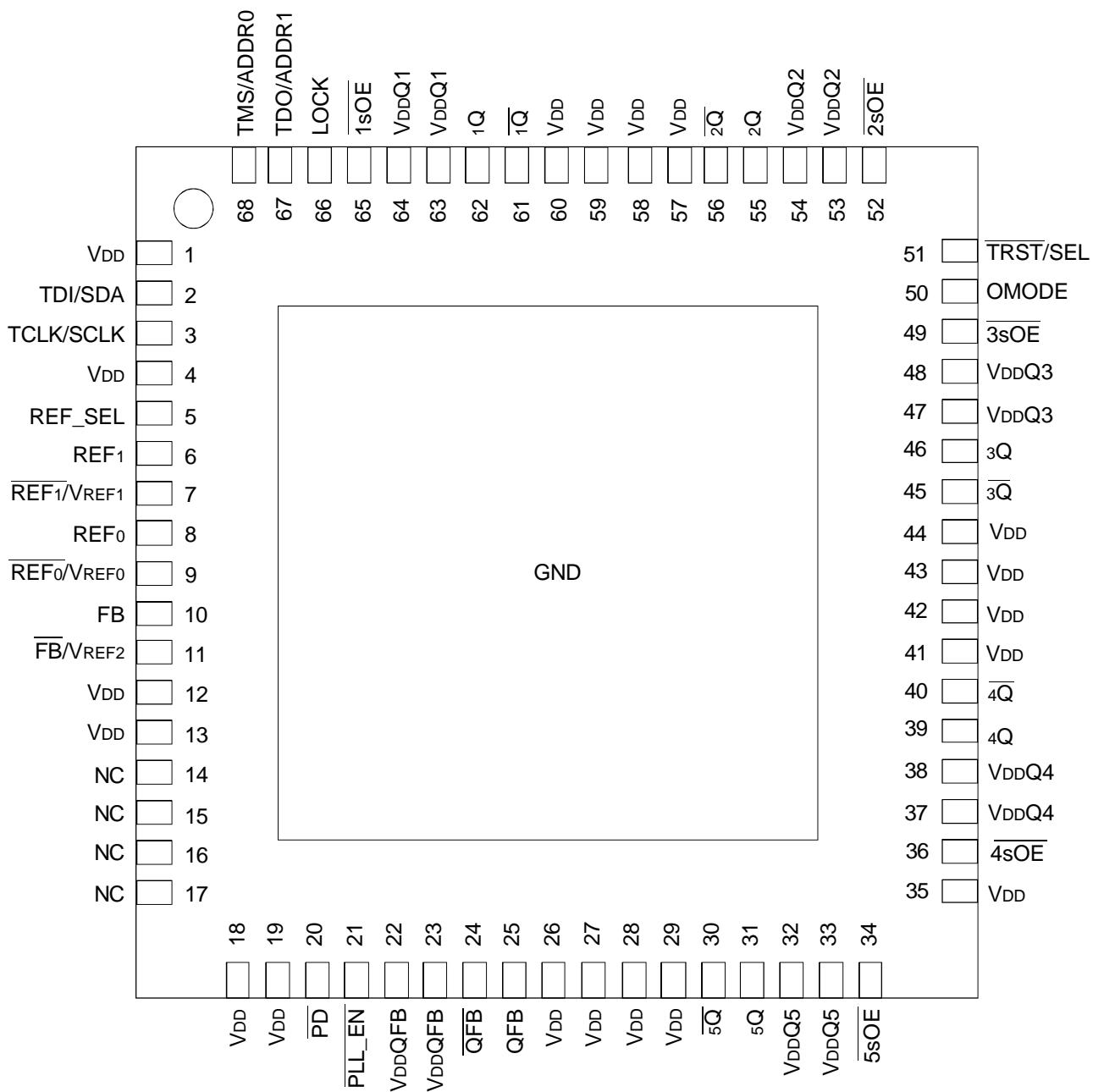
The IDT5T9891 features a user-selectable, single-ended or differential input to six differential outputs. The differential clock driver also acts as a translator from a differential HSTL, eHSTL, 1.8V/2.5V LVTTL, LVEPECL, or single-ended 1.8V/2.5V LVTTL input to HSTL, eHSTL, or 1.8V/2.5V LVTTL outputs. Each output bank can be individually configured to be either HSTL, eHSTL, 2.5V LVTTL, or 1.8V LVTTL, including the feedback bank. Also, each clock input can be individually configured to accept 2.5V LVTTL, 1.8V LVTTL, or differential signals. The outputs can be synchronously enabled/disabled. The differential outputs can be synchronously enabled/disabled.

Furthermore, all the outputs can be synchronized with the positive edge of the REF clock input or the negative edge of REF.

INDUSTRIAL TEMPERATURE RANGE

JUNE 2004

DSC - 6505/13

FUNCTIONAL BLOCK DIAGRAM

PIN CONFIGURATION

Top pins (68–52): TMS/ADDR0 (68), TDO/ADDR1 (67), LOCK (66), 1sOE̅ (65), VDDQ1 (64), VDDQ1 (63), 1Q (62), 1Q̅ (61), VDD (60), VDD (59), VDD (58), VDD (57), 2Q̅ (56), 2Q (55), VDDQ2 (54), VDDQ2 (53), 2sOE̅ (52)

Left pins (1–17):
- 1 — VDD
- 2 — TDI/SDA
- 3 — TCLK/SCLK
- 4 — VDD
- 5 — REF_SEL
- 6 — REF1
- 7 — REF̅1̅/VREF1
- 8 — REF0
- 9 — REF̅0̅/VREF0
- 10 — FB
- 11 — FB̅/VREF2
- 12 — VDD
- 13 — VDD
- 14 — NC
- 15 — NC
- 16 — NC
- 17 — NC

Center: GND

Right pins (51–35):
- 51 — TRST̅/SEL
- 50 — OMODE
- 49 — 3sOE̅
- 48 — VDDQ3
- 47 — VDDQ3
- 46 — 3Q
- 45 — 3Q̅
- 44 — VDD
- 43 — VDD
- 42 — VDD
- 41 — VDD
- 40 — 4Q̅
- 39 — 4Q
- 38 — VDDQ4
- 37 — VDDQ4
- 36 — 4sOE̅
- 35 — VDD

Bottom pins (18–34): VDD (18), VDD (19), PD̅ (20), PLL_EN (21), VDDQFB (22), VDDQFB (23), QFB̅ (24), QFB (25), VDD (26), VDD (27), VDD (28), VDD (29), 5Q̅ (30), 5Q (31), VDDQ5 (32), VDDQ5 (33), 5sOE̅ (34)

VFQFPN
TOP VIEW

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Description	Max	Unit
V_{DDQN}, V_{DD}	Power Supply Voltage[2]	–0.5 to +3.6	V
V_I	Input Voltage	–0.5 to +3.6	V
V_O	Output Voltage	–0.5 to V_{DDQ} +0.5	V
V_{REF}	Reference Voltage[3]	–0.5 to +3.6	V
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	–65 to +165	°C

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. V_{DDQN} and V_{DD} internally operate independently. No power sequencing requirements need to be met.
3. Not to exceed 3.6V.

CAPACITANCE (T_A = +25°C, f = 1MHz, V_{IN} = 0V)

Parameter	Description	Min.	Typ.	Max.	Unit
C_{IN}	Input Capacitance	2.5	3	3.5	pF
C_{OUT}	Output Capacitance	—	6.3	7	pF

NOTE:

1. Capacitance applies to all inputs except JTAG/I2C signals, SEL, ADDR0, and ADDR1.

RECOMMENDED OPERATING RANGE

Symbol	Description	Min.	Typ.	Max.	Unit
T_A	Ambient Operating Temperature	–40	+25	+85	°C
V_{DD}[1]	Internal Power Supply Voltage	2.3	2.5	2.7	V
V_{DDQN}[1]	HSTL Output Power Supply Voltage	1.4	1.5	1.6	V
	Extended HSTL and 1.8V LVTTL Output Power Supply Voltage	1.65	1.8	1.95	V
	2.5V LVTTL Output Power Supply Voltage		V_{DD}		V
V_T	Termination Voltage		V_{DDQN} / 2		V

NOTE:

1. All power supplies should operate in tandem. If V_{DD} or V_{DDQN} is at maximum, then V_{DDQN} or V_{DD} (respectively) should be at maximum, and vice-versa.

PIN DESCRIPTION

Symbol	I/O	Type	Description
REF[1:0]	I	Adjustable[1]	Clock input. REF[1:0] is the "true" side of the differential clock input. If operating in single-ended mode, REF[1:0] is the clock input.
$\overline{REF}$[1:0]/ V_{REF}[1:0]	I	Adjustable[1]	Complementary clock input. $\overline{REF}$[1:0]/V_{REF}[1:0] is the "complementary" side of REF[1:0] if the input is in differential mode. If operating in single-ended mode, $\overline{REF}$[1:0]/V_{REF}[1:0] is left floating. For single-ended operation in differential mode, $\overline{REF}$[1:0]/V_{REF}[1:0] should be set to the desired toggle voltage for REF[1:0]: 2.5V LVTTL　　　V_{REF} = 1250mV (SSTL2 compatible) 1.8V LVTTL, eHSTL　　　V_{REF} = 900mV HSTL　　　V_{REF} = 750mV LVEPECL　　　V_{REF} = 1082mV
FB	I	Adjustable[1]	Clock input. FB is the "true" side of the differential feedback clock input. If operating in single-ended mode, FB is the feedback clock input.
$\overline{FB}$/V_{REF2}	I	Adjustable[1]	Complementary feedback clock input. $\overline{FB}$/V_{REF2} is the "complementary" side of FB if the input is in differential mode. If operating in single-ended mode, $\overline{FB}$/V_{REF2} is left floating. For single-ended operation in differential mode, $\overline{FB}$/V_{REF2} should be set to the desired toggle voltage for FB: 2.5V LVTTL　　　V_{REF} = 1250mV (SSTL2 compatible) 1.8V LVTTL, eHSTL　　　V_{REF} = 900mV HSTL　　　V_{REF} = 750mV LVEPECL　　　V_{REF} = 1082mV

NOTE:

1. Inputs are capable of translating the following interface standards. User can select between:

　Single-ended 2.5V LVTTL levels

　Single-ended 1.8V LVTTL levels

　or

　Differential 2.5V/1.8V LVTTL levels

　Differential HSTL and eHSTL levels

　Differential LVEPECL levels

PIN DESCRIPTION, CONTINUED

Symbol	I/O	Type	Description
REF_SEL	I	LVTTL[1]	Reference clock select. When LOW, selects REF0 and $\overline{REF}$0/V$_{REF0}$. When HIGH, selects REF1 and $\overline{REF}$1/V$_{REF1}$.
$\overline{nsOE}$	I	LVTTL[1]	Synchronous output enable/disable. Each outputs's enable/disable state can be controlled either with the $\overline{nsOE}$ pin or through JTAG or I^{2}C programming, corresponding bits 52 - 56. When the $\overline{nsOE}$ is HIGH or the corresponding Bit (52 - 56) is 1, the output will be synchronously disabled. When the $\overline{nsOE}$ is LOW and the corresponding Bit (52 - 56) is 0, the output will be enabled. (See JTAG/I^{2}C Serial Configuration table.)
QFB	O	Adjustable[2]	Feedback clock output
$\overline{QFB}$	O	Adjustable[2]	Complementary feedback clock output
nQ	O	Adjustable[2]	Clock outputs
$\overline{nQ}$	O	Adjustable[2]	Complementary clock outputs
$\overline{PLL\_EN}$	I	LVTTL[1]	PLL enable/disable control. The PLL's enable/disable state can be controlled either with the $\overline{PLL\_EN}$ pin or through JTAG or I^{2}C programming, corresponding Bit 57. When $\overline{PLL\_EN}$ is HIGH or the corresponding Bit 57 is 1, the PLL is disabled and REF[1:0] goes to all outputs. When $\overline{PLL\_EN}$ is LOW and the corresponding Bit 57 is 0, the PLL will be active.
$\overline{PD}$	I	LVTTL[1]	Power down control. When $\overline{PD}$ is LOW, the inputs are disabled and internal switching is stopped. The OMODE pin in conjunction with the corresponding Bit 59 selects whether the outputs are gated LOW/HIGH or tri-stated. When OMODE is HIGH or Bit 59 is 1, Bit 58 determines the level at which the outputs stop. When Bit 58 is 0/1, the nQ and QFB are stopped in a HIGH/LOW state, while the $\overline{nQ}$ and $\overline{QFB}$ are stopped in a LOW/HIGH state. When OMODE is LOW and Bit 59 is 0, the outputs are tri-stated. Set $\overline{PD}$ HIGH for normal operation. (See JTAG/I^{2}C Serial Configuration table.)
LOCK	O	LVTTL	PLL lock indication signal. HIGH indicates lock. LOW indicates that the PLL is not locked and outputs may not be synchronized to the inputs. The output will be 2.5V LVTTL.
OMODE	I	LVTTL[1]	Output disable control. Used in conjunction with $\overline{nsOE}$ and $\overline{PD}$. The outputs' disable state can be controlled either with the OMODE pin or through JTAG or I^{2}C programming, corresponding Bit 59. When OMODE is HIGH or the corresponding Bit 59 is 1, the outputs' disable state will be gated and Bit 58 will determine the level at which the outputs stop. When Bit 58 is 0/1, the nQ and QFB are stopped in a HIGH/LOW state, while the $\overline{nQ}$ and $\overline{QFB}$ are stopped in a LOW/HIGH state. When OMODE is LOW and its corresponding bit 59 is 0, the outputs disable state will be the tri-state. (See JTAG/I^{2}C Serial Configurations tables.)
$\overline{TRST}$/SEL	I/I	LVTTL/ LVTTL[4,5] 3-Level[3,4,5]	$\overline{TRST}$ - Active LOW input to asynchronously reset the JTAG boundary-scan circuit. SEL - Select programming interface control for the dual-function pins. When HIGH, the dual-function pins are set for JTAG programming. When LOW, the dual-function pins are set for I^{2}C programming and the JTAG interface is asynchronously placed in the Test Logic Reset state.
TDO/ADDR1	O/I	LVTTL/ 3-Level[3,4,5]	TDO - Serial data output pin for instructions as well as test and programming data. Data is shifted in on the falling edge of TCLK. The pin is tri-stated if data is not being shifted out of the device. ADDR1 - Used to define a unique I^{2}C address for this device. Only for I^{2}C programming. (See JTAG/I^{2}C Serial Interface Description.)
TMS/ADDR0	I/I	LVTTL/ LVTTL[4,5]	TMS - Input pin that provides the control signal to determine the transitions of the JTAG TAP controller state machine. Transitions within the state machine occur at the rising edge of TCLK. Therefore, TMS must be set up before the rising edge of TCLK. TMS is evaluated on the rising edge of TCLK. ADDR0 - Used to define a unique I^{2}C address for this device. Only for I^{2}C programming. (See JTAG/I^{2}C Serial Interface Description.)
TCLK/SCLK	I/I	LVTTL/ LVTTL[4,5]	TCLK - The clock input to the JTAG BST circuitry. SCLK - Serial clock for I^{2}C programming
TDI/SDA	I/I	LVTTL/	TDI - Serial input pin for instructions as well as test and programming data. Data is shifted in on the rising edge of TCLK. SDA - Serial data (see JTAG/I^{2}C Serial Description table)
V$_{DDQN}$		PWR	Power supply for each pair of outputs. When using 2.5V LVTTL, 1.8V LVTTL, HSTL, or eHSTL outputs, V$_{DDQN}$ should be set to its corresponding outputs (see Front Block Diagram). When using 2.5V LVTTL outputs, V$_{DDQN}$ should be connected to V$_{DD}$.
V$_{DD}$		PWR	Power supply for phase locked loop, lock output, inputs, and other internal circuitry
GND		PWR	Ground

NOTES:
1. Pins listed as LVTTL inputs can be configured to accept 1.8V or 2.5V signals through the use of the I^{2}C/JTAG programming, bit 61. (See JTAG/I^{2}C Serial Description.)
2. Outputs are user selectable to drive 2.5V, 1.8V LVTTL, eHSTL, or HSTL interface levels when used with the appropriate V$_{DDQN}$ voltage.
3. 3-level inputs are static inputs and must be tied to V$_{DD}$ or GND or left floating. These inputs are not hot-insertable or over voltage tolerant.
4. The JTAG (TDO, TMS, TCLK, and TDI) and I^{2}C (ADDR1, ADDR0, SCLK, and SDA) signals share the same pins (dual-function pins) for which the $\overline{TRST}$/SEL pin will select between the two programming interfaces.
5. JTAG and I^{2}C pins accept 2.5V signals. The JTAG input pins (TMS, TCLK, TDI, $\overline{TRST}$) will also accept 1.8V signals.

JTAG/ I²C SERIAL DESCRIPTION

Bit	Description
95:62	Reserved Bits. Set bits 95:62 to '0'.
61	Input interface selection for control pins (REF_SEL, $\overline{PD}$, $\overline{PLL\_EN}$, OMODE, $\overline{nSOE}$). When bit 61 is '1', the control pins are 2.5V LVTTL. When bit 61 is '0', the control pins are 1.8V LVTTL.
60	VCO frequency range. When '0', range is 50MHz-125MHz. When '1', range is 100MHz-250MHz.
59	Output's disable state. See corresponding external pin OMODE for Pin Description table.
58	Positive/Negative edge control. When '0'/'1', the outputs are synchronized with the negative/positive edge of the reference clock.
57	PLL enable/disable. See corresponding external pin $\overline{PLL\_EN}$ in Pin Description table.[1]
56	Output disable/enable for 1Q[1:0] outputs. See corresponding external pin $\overline{1SOE}$ in Pin Description table.
55	Output disable/enable for 2Q[1:0] outputs. See corresponding external pin $\overline{2SOE}$ in Pin Description table.
54	Output disable/enable for 3Q[1:0] outputs. See corresponding external pin $\overline{3SOE}$ in Pin Description table.
53	Output disable/enable for 4Q[1:0] outputs. See corresponding external pin $\overline{4SOE}$ in Pin Description table.
52	Output disable/enable for 5Q[1:0] outputs. See corresponding external pin $\overline{5SOE}$ in Pin Description table.
51	FB Divide-by-N selection
50	FB Divide-by-N selection
49	FB Divide-by-N selection
48	FB Divide-by-N selection
47	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 1
46	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 1
45	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 2
44	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 2
43	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 3
42	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 3
41	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 4
40	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 4
39	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 5
38	Output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on bank 5
37	FB output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on FB bank
36	FB output drive strength selection for 2.5V LVTTL, 1.8V LVTTL, or HSTL/eHSTL on FB bank
35	REF0 Input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
34	REF0 Input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
33	REF1 input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
32	REF1 input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
31	FB input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
30	FB input interface selection for 2.5V LVTTL, 1.8V LVTTL, or Differential
29	Skew or frequency selection for bank 1
28	Skew or frequency selection for bank 1
27	Skew or frequency selection for bank 1
26	Skew or frequency selection for bank 1
25	Skew or frequency selection for bank 1
24	Skew or frequency selection for bank 2
23	Skew or frequency selection for bank 2
22	Skew or frequency selection for bank 2

NOTE:

1. Only for EEPROM operation; bit 57 must be set to 0 to enable the PLL for proper EEPROM operation. The EEPROM access times are based on the VCO frequency of the PLL (refer to the EEPROM Operation section).

JTAG/ I²C SERIAL DESCRIPTION, CONT.

Bit	Description
21	Skew or frequency selection for bank 2
20	Skew or frequency selection for bank 2
19	Skew or frequency selection for bank 3
18	Skew or frequency selection for bank 3
17	Skew or frequency selection for bank 3
16	Skew or frequency selection for bank 3
15	Skew or frequency selection for bank 3
14	Skew or frequency selection for bank 4
13	Skew or frequency selection for bank 4
12	Skew or frequency selection for bank 4
11	Skew or frequency selection for bank 4
10	Skew or frequency selection for bank 4
9	Skew or frequency selection for bank 5
8	Skew or frequency selection for bank 5
7	Skew or frequency selection for bank 5
6	Skew or frequency selection for bank 5
5	Skew or frequency selection for bank 5
4	Skew or frequency selection for FB bank
3	Skew or frequency selection for FB bank
2	Skew or frequency selection for FB bank
1	Skew or frequency selection for FB bank
0	Skew or frequency selection for FB bank

JTAG/ I²C SERIAL CONFIGURATIONS: OUTPUT ENABLE/DISABLE

Bit 59 (OMODE)	Bit 56-52 (nsOE)	Output
X (X)	0 and (L)	Normal Operation
0 and (L)	1 or (H)	Tri-Sate
1 or (H)	1 or (H)	Gated[1]

NOTE:

1. OMODE and its corresponding Bit 59 selects whether the outputs are gated LOW/HIGH or tri-stated. When OMODE is HIGH or the corresponding Bit 59 is 1, the outputs' disable state will be gated. Bit 58 determines the level at which the outputs stop. When Bit 58 is 0/ 1, the nQ and QFB are stopped in a HIGH/LOW state, while the $\overline{nQ}$ and $\overline{QFB}$ are stopped in a LOW/HIGH state. When OMODE is LOW and its corresponding Bit 59 is 0, the outputs' disable state will be the tri-state.

JTAG/ I²C SERIAL CONFIGURATIONS: POWERDOWN

$\overline{PD}$	Bit 59 (OMODE)	Output
H	X (X)	Normal Operation
L	0 and (L)	Tri-Sate
L	1 or (H)	Gated[1]

NOTE:

1. OMODE and its corresponding Bit 59 selects whether the outputs are gated LOW/HIGH or tri-stated. When OMODE is HIGH or the corresponding Bit 59 is 1, the outputs' disable state will be gated. Bit 58 determines the level at which the outputs stop. When Bit 58 is 0/ 1, the nQ and QFB are stopped in a HIGH/LOW state, while the $\overline{nQ}$ and $\overline{QFB}$ are stopped in a LOW/HIGH state. When OMODE is LOW and its corresponding Bit 59 is 0, the outputs' disable state will be the tri-state.

JTAG/ I²C SERIAL CONFIGURATIONS: CLOCK INPUT INTERFACE SELECTION[1]

Bit 31, 33, 35	Bit 30, 32, 34	Interface
0	0	Differential[2]
0	1	2.5V LVTTL
1	1	1.8V LVTTL

NOTES:

1. All other states that are undefined in the table will be reserved.
2. Differential input interface for HSTL/eHSTL, LVEPECL (2.5V), and 2.5V/1.8V LVTTL.

JTAG/ I²C SERIAL CONFIGURATIONS: OUTPUT DRIVE STRENGTH SELECTION[1]

Bit 37, 39, 41, 43, 45, 47	Bit 36, 38, 40, 42, 44, 46	Interface
0	0	2.5V LVTTL
0	1	1.8V LVTTL
1	0	HSTL/eHSTL

NOTE:

1. All other states that are undefined in the table will be reserved.

JTAG/ I²C SERIAL CONFIGURATIONS: SKEW OR FREQUENCY SELECT[1]

Bit 4, 9, 14, 19, 24, 29	Bit 3, 8, 13, 18, 23, 28	Bit 2, 7, 12, 17, 22, 27	Bit 1, 6, 11, 16, 21, 26	Bit 0, 5, 10, 15, 20, 25	Output Skew
0	0	0	0	1	+7tu
0	0	0	1	0	+6tu
0	0	0	1	1	+5tu
0	0	1	0	0	+4tu
0	0	1	0	1	+3tu
0	0	1	1	0	+2tu
0	0	1	1	1	+1tu
0	0	0	0	0	Zero Skew
0	1	0	0	1	-1tu
0	1	0	1	0	-2tu
0	1	0	1	1	-3tu
0	1	1	0	0	-4tu
0	1	1	0	1	-5tu
0	1	1	1	0	-6tu
0	1	1	1	1	-7tu
1	0	0	0	0	Inverted
1	0	0	0	1	Divide-by-2
1	0	0	1	0	Divide-by-4

NOTE:

1. All other states that are undefined in the table will result in zero skew.

JTAG/ I²C SERIAL CONFIGURATIONS: FB DIVIDE-BY-N[1]

Bit 51	Bit 50	Bit 49	Bit 48	Divide-by-N	Permitted Output Divide-by-N connected to FB and F̅B̅/VREF2 [2]
0	0	0	0	1	1, 2, 4
0	0	0	1	2	1, 2
0	0	1	0	3	1
0	0	1	1	4	1, 2
0	1	0	0	5	1, 2
0	1	0	1	6	1, 2
0	1	1	0	8	1
0	1	1	1	10	1
1	0	0	0	12	1

NOTES:

1. All other states that are undefined in the table will be reserved.
2. Permissible output division ratios connected to FB and F̅B̅/VREF2. The frequencies of the REF[1:0] and R̅E̅F̅ [1:0]/VREF[1:0] inputs will be Fvco/N when the parts are configured for frequency multiplication by using an undivided output for FB and F̅B̅/VREF2 and setting N (N = 1-6, 8, 10, 12).

JTAG/ I²C SERIAL CONFIGURATIONS: VCO FREQUENCY SELECT

Bit 60	Min.	Max.
0	50Mhz	125MHz
1	100MHz	250Mhz

PROGRAMMABLE SKEW

Output skew with respect to the REF[1:0] and $\overline{REF}$[1:0]/VREF[1:0] input is adjustable to compensate for PCB trace delays, backplane propagation delays or to accommodate requirements for special timing relationships between clocked components. Skew is selectable as a multiple of a time unit (tu) which ranges from 250ps to 1.25ns (see Programmable Skew Range and Resolution Table). There are 18 skew/divide configurations available for each output pair. These configurations are chosen through JTAG/I²C programming.

PROGRAMMABLE SKEW RANGE AND RESOLUTION TABLE

	Bit 60 = 0	Bit 60 = 1	Comments
Timing Unit Calculation (tu)	1/(16 x FNOM)	1/(16 x FNOM)	
VCO Frequency Range (FNOM)[1,2]	50 to 125MHz	100 to 250MHz	
Skew Adjustment Range[3]			
Max Adjustment:	±8.75ns	±4.375ns	ns
	±157.5°	±157.5°	Phase Degrees
	±43.75%	±43.75%	% of Cycle Time
Example 1, FNOM = 50MHz	tu = 1.25ns	—	
Example 2, FNOM = 75MHz	tu = 0.833ns	—	
Example 3, FNOM = 100MHz	tu = 0.625ns	tu = 0.625ns	
Example 4, FNOM = 150MHz	—	tu = 0.417ns	
Example 5, FNOM = 200MHz	—	tu = 0.313ns	
Example 6, FNOM = 250MHz	—	tu = 0.25ns	

NOTES:
1. The device may be operated outside recommended frequency ranges without damage, but functional operation is not guaranteed.
2. The VCO frequency always appears at nQ and $\overline{nQ}$ outputs when they are operated in their undivided modes. The frequency appearing at the REF[1:0] and $\overline{REF}$[1:0]/VREF[1:0] and FB and $\overline{FB}$/VREF2 inputs will be FNOM when the QFB and $\overline{QFB}$ are undivided and FB divide-by-1. The frequency of the REF[1:0] and $\overline{REF}$[1:0]/VREF[1:0] and FB and $\overline{FB}$/VREF2 inputs will be FNOM /2 or FNOM /4 when the part is configured for frequency multiplication by using a divided QFB and $\overline{QFB}$ and setting FB divide-by-1. Using the FB divide-by-N configuration inputs allows a different method for frequency multiplication (see JTAG/I²C Serial Configurations: FB Divide-by-N).
3. Skew adjustment range assumes that a zero skew output is used for feedback. If a skewed QFB and $\overline{QFB}$ output is used for feedback, then adjustment range will be greater. For example if a 4tu skewed output is used for feedback, all other outputs will be skewed –4tu in addition to whatever skew value is programmed for those outputs. 'Max adjustment' range applies to all output pairs where ±7tu skew adjustment is possible and at the lowest FNOM value.

EXTERNAL DIFFERENTIAL FEEDBACK

By providing a dedicated external differential feedback, the IDT5T9891 gives users flexibility with regard to divide selection. The FB and $\overline{FB}$/VREF2 signals are compared with the input REF[1:0] and $\overline{REF}$[1:0]/VREF[1:0] signals at the phase detector in order to drive the VCO. Phase differences cause the VCO of the PLL to adjust upwards or downwards accordingly.

An internal loop filter moderates the response of the VCO to the phase detector. The loop filter transfer function has been chosen to provide minimal jitter (or frequency variation) while still providing accurate responses to input frequency changes.

MASTER RESET FUNCTIONALITY

The IDT5T9891 performs a reset of the internal output divide circuitry when all five output banks are disabled by toggling the $\overline{nSOE}$ pins HIGH. When one or more banks of outputs are enabled by toggling the $\overline{nSOE}$ LOW (if the corresponding $\overline{nSOE}$ programming bits are also set LOW), the divide circuitry starts again from a known state. In the case that the FB output is selected for divide-by-2 or divide-by-4, the FB output will stop toggling while all five $\overline{nSOE}$ pins and bits are LOW, and loss of lock will occur.

INPUT/OUTPUT SELECTION[1]

Input	Output[2]
2.5V LVTTL SE	2.5V LVTTL,
1.8V LVTTL SE	1.8V LVTTL,
2.5V LVTTL DSE	HSTL,
1.8V LVTTL DSE	eHSTL
LVEPECL DSE	
eHSTL DSE	
HSTL DSE	
2.5V LVTTL DIF	
1.8V LVTTL DIF	
LVEPECL DIF	
eHSTL DIF	
HSTL DIF	

NOTES:
1. The INPUT/OUTPUT SELECTION Table describes the total possible combinations of input and output interfaces. Single-Ended (SE) inputs in a single-ended mode require the $\overline{REF}$[1:0] /VREF[1:0] and $\overline{FB}$/VREF2 pins to be left floating. Differential Single-Ended (DSE) is for single-ended operation in differential mode, requiring VREF[1:0] and VREF2. Differential (DIF) inputs are used only in differential mode.
2. For each output bank.

I²C SERIAL INTERFACE CONTROL

The I²C interface permits the configuration of the IDT5T9891. The IDT5T9891 is a read/write slave device meeting Philips I²C bus specifications. The I²C bus is controlled by a master device that generates the serial clock SCLK, controls bus access, and generates the START and STOP conditions while the device works as a slave. Both master and slave can operate as a transmitter and receiver but the master device determines which mode is activated.

BUS CONDITIONS

Data transfer on the bus can only be initiated when the bus is not busy. During data transfer, the data line (SDA) must remain stable whenever the clock line (SCLK) is high. Changes in the data line while the clock line is high will be interpreted by the device as a START or STOP condition. The following bus conditions are defined by the I²C bus protocol and are illustrated in figure 1.

NOT BUSY

Both the data (SDA) and clock (SCLK) lines remain high to indicate the bus is not busy.

START DATA TRANSFER

A high to low transition of the SDA line while the SCLK input is high indicates a START condition. All commands to the device must be preceded by a START condition.

STOP DATA TRANSFER

A low to high transition of the SDA line while SCLK is held high indicates a STOP condition. All commands to the device must be followed by a STOP condition.

DATA VALID

The state of the SDA line represents valid data if the SDA line is stable for the duration of the high period of the SCLK line after a START condition occurs. The data on the SDA line must be changed only during the low period of the SCLK signal. There is one clock pulse per data bit. Each data transfer is initiated by a START condition and terminated with a STOP condition.

ACKNOWLEDGE

When addressed, the receiving device is required to generate an Acknowledge after each byte is received. The master device must generate an extra clock pulse to coincide with the Acknowledge bit. The acknowledging device must pull the SDA line low during the high period of the master acknowledge clock pulse. Setup and hold times must be taken into account.

I²C BUS OPERATION

The IDT5T9891 I²C interface supports Standard-Mode (100kHz) and Fast-Mode (400kHz) data transfer rates. Data is transferred in bytes in sequential order from the lowest to highest byte. After generating a START condition, the bus master broadcasts a 7-bit slave address followed by a read/write bit.

I²C ADDRESS

A7	A6	A5	A4	A3	A2	A1
1	1	0	1	X	X	X

Address A0 is the read/write bit and is set to '0' for writes and '1' for reads. The ADDR0 and ADDR1 tri-level pins allow the last three bits of the 7-bit address to be defined by the user.

ADDR1	ADDR0	A3	A2	A1
LOW	LOW	0	0	0
LOW	MID	0	0	1
LOW	HIGH	0	1	0
MID	LOW	0	1	1
MID	MID	1	0	0
MID	HIGH	1	0	1
HIGH	LOW	1	1	0
HIGH	MID	1	1	1
HIGH	HIGH	1	1	0

WRITE OPERATION
(see I²C Interface Definition for ProgWrite)

To initiate a write operation (ProgWrite), the read/write bit is set to '0'. During the write operation, the first two bytes transferred must be the Device Address followed by the Command Code. The internal programming registers of the device ignore these first two bytes. The subsequent bytes are the Data Bytes, which total twelve. All twelve Data Bytes must be written into the device during the write operation in order for the internal programming registers to be updated. If a STOP condition is generated before the 12th Data Byte, the internal programming registers will remain unchanged to prevent an invalid PLL configuration. An Acknowledge by the device between each byte must occur before the next byte is sent. After the transfer of the 12th Data Byte, an Acknowledge signal will be sent to the bus master after which it will generate a STOP condition. Once the STOP condition has occurred, the internal programming registers of the device will be updated.

READ OPERATION
(see I²C Interface Definition for ProgRead)

To initiate a read operation (ProgRead), the read/write bit is set to '1'. During the read operation, there will be a total of fourteen data bytes returned following an Acknowledge of the device address. The first two data bytes are the ID Byte and a Reserved Byte, in that order. The subsequent bytes are the same twelve Data Bytes that were written during the write operation. The read back can be terminated at any time by issuing a STOP condition.

I²C ID BYTE

ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0
0	0	0	0	0	1	1	1

EEPROM OPERATION
(see I²C Interface Definition for the EEPROM instructions)

The IDT5T9891 can also store its configuration in internal EEPROM. The contents of the device's internal programming registers can be saved to the EEPROM by issuing a save instruction (ProgSave) and can be loaded back to the internal programming registers by issuing a restore instruction (ProgRestore). To initiate a save or restore, only two bytes are transferred. The Device Address is issued with the read/write bit set to '0' followed by the appropriate Command Code. The save or restore instruction executes after the STOP condition is received, during which time the IDT5T9891 will not generate Acknowledge bits. The device is ready to accept a new programming instruction once it Acknowledges its 7-bit address. The time it takes for the save and restore instructions to complete depends on the PLL oscillator frequency, F_{VCO}. The restore time, $T_{RESTORE}$, and the save time, T_{SAVE}, can be calculated as follows:

$$T_{RESTORE} = 1.23 \times 10^6 / F_{VCO} \quad (mS)$$
$$T_{SAVE} = 3.09 \times 10^6 / F_{VCO} + 52 \quad (mS)$$

In order for the save and restore instructions to function properly, the IDT5T9891 must not be in power-down mode ($\overline{PD}$ must be HIGH), and the PLL must be enabled ($\overline{PLL\_EN}$ must be LOW and Bit 57 = 0).

On power-up of the IDT5T9891, an automatic restore is performed to load the EEPROM contents into the internal programming registers. The auto-restore will not function properly if the device is in power-down mode ($\overline{PD}$ must be HIGH). The device's auto-restore feature will function regardless of the state of the $\overline{PLL\_EN}$ pin or Bit 57. The IDT5T9891 will be ready to accept a programming instruction once it acknowledges its 7-bit I²C address. The time it takes for the device to complete the auto-restore is approximately 3ms.

PROGRAMMING NOTES

Once the IDT5T9891 has been programmed either with a ProgWrite or ProgRestore instruction, the device will attempt to achieve phase lock using the new PLL configuration. If there is a valid REF and FB input clock connected to the device and it does not achieve lock, the user should issue a ProgRead instruction to confirm that the PLL configuration data is valid.

On power-up and before the automatic ProgRestore instruction has completed, the internal programming registers will contain the value of '0' for all bits 95:0. The PLL will remain at the minimum frequency and will not achieve phase lock until after the automatic restore is completed. If the outputs are enabled by the $\overline{nSOE}$ pins, the outputs will toggle at the minimum frequency. If the outputs are disabled by the $\overline{nSOE}$ pins and the OMODE pin is set HIGH, the nQ and QFB are stopped HIGH, while $\overline{nQ}$ and $\overline{QFB}$ are stopped LOW.
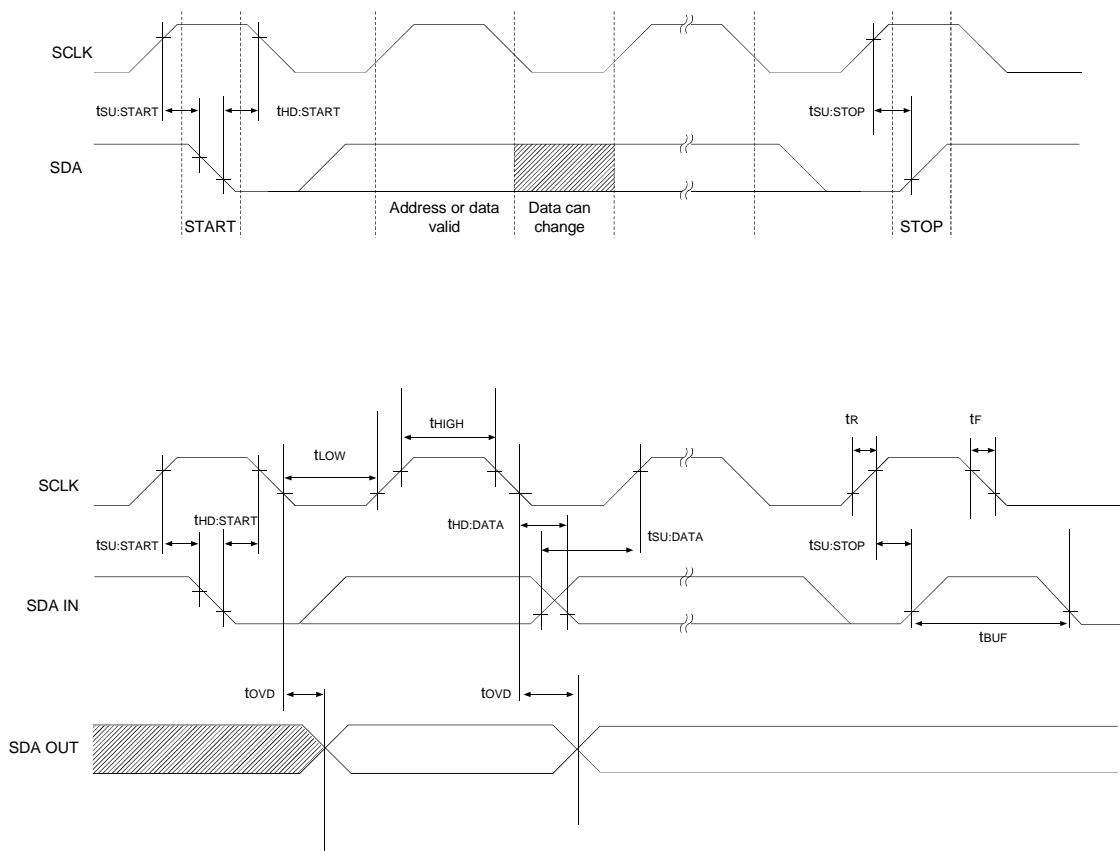

Figure 1: I²C Timing Data

I²C INTERFACE DEFINITION

ProgWrite

	Device Address	W		Command Code		Data		
S	7'b1101xxx	0	A	8'bxxxxxx00	A	Data Byte 1 (Bits 95 - 88)	A	. . .
	MSB	LSB		MSB	LSB	Data Byte 2	A	. . .
						Data Byte 3	A	. . .
						Data Byte 4	A	. . .
						Data Byte 5	A	. . .
						Data Byte 6	A	. . .
						Data Byte 7	A	. . .
						Data Byte 8	A	. . .
						Data Byte 9	A	. . .
						Data Byte 10	A	. . .
						Data Byte 11	A	. . .
						Data Byte 12 (Bits 7 - 0)	A	P

ID Byte:

Part #	ID
5T9891	00000111

ProgRead

	Device Address	R		ID Byte		
S	7'b1101xxx	1	A	8'b00000111	A	. . .
				Reserved Byte	A	. . .
				Data Byte 1 (Bits 95 - 88)	A	. . .
				Data Byte 2	A	. . .
				Data Byte 3	A	. . .
				Data Byte 4	A	. . .
				Data Byte 5	A	. . .
				Data Byte 6	A	. . .
				Data Byte 7	A	. . .
				Data Byte 8	A	. . .
				Data Byte 9	A	. . .
				Data Byte 10	A	. . .
				Data Byte 11	A	. . .
				Data Byte 12 (Bits 7 - 0)	A	P

ProgSave

	Device Address	W		Command Code		
S	7'b1101xxx	0	A	8'bxxxxxx01	A	P

ProgRestore

	Device Address	W		Command Code		
S	7'b1101xxx	0	A	8'bxxxxxx10	A	P

I²C BUS DC CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IH}	Input HIGH Level		0.7 * V_{DD}			V
V_{IL}	Input LOW Level				0.3 * V_{DD}	V
V_{HYS}	Hysteresis of Inputs		0.05 * V_{DD}			V
I_{IN}	Input Leakage Current				±1.0	µA
V_{OL}	Output LOW Voltage	I_{OL} = 3 mA			0.4	V

I²C BUS AC CHARACTERISTICS FOR STANDARD MODE

Symbol	Parameter	Min	Typ	Max	Unit
F_{SCLK}	Serial Clock Frequency (SCLK)	0		100	KHz
t_{BUF}	Bus free time between STOP and START	4.7			µs
$t_{SU:START}$	Setup Time, START	4.7			µs
$t_{HD:START}$	Hold Time, START	4			µs
$t_{SU:DATA}$	Setup Time, data input (SDA)	250			ns
$t_{HD:DATA}$	Hold Time, data input (SDA)[1]	0			µs
t_{OVD}	Output data valid from clock			3.45	µs
C_B	Capacitive Load for Each Bus Line			400	pF
t_R	Rise Time, data and clock (SDA, SCLK)			1000	ns
t_F	Fall Time, data and clock (SDA, SCLK)			300	ns
t_{HIGH}	HIGH Time, clock (SCLK)	4			µs
t_{LOW}	LOW Time, clock (SCLK)	4.7			µs
$t_{SU:STOP}$	Setup Time, STOP	4			µs

NOTE:
1. A device must internally provide a hold time of at least 300ns for the SDA signal (referred to the V_{IHMIN} of the SCLK signal) to bridge the undefined region of the falling edge of SCLK.

I²C BUS AC CHARACTERISTICS FOR FAST MODE

Symbol	Parameter	Min	Typ	Max	Unit
F_{SCLK}	Serial Clock Frequency (SCLK)	0		400	KHz
t_{BUF}	Bus free time between STOP and START	1.3			µs
$t_{SU:START}$	Setup Time, START	0.6			µs
$t_{HD:START}$	Hold Time, START	0.6			µs
$t_{SU:DATA}$	Setup Time, data input (SDA)	100			ns
$t_{HD:DATA}$	Hold Time, data input (SDA)[1]	0			µs
t_{OVD}	Output data valid from clock			0.9	µs
C_B	Capacitive Load for Each Bus Line			400	pF
t_R	Rise Time, data and clock (SDA, SCLK)	20 + 0.1 * C_B		300	ns
t_F	Fall Time, data and clock (SDA, SCLK)	20 + 0.1 * C_B		300	ns
t_{HIGH}	HIGH Time, clock (SCLK)	0.6			µs
t_{LOW}	LOW Time, clock (SCLK)	1.3			µs
$t_{SU:STOP}$	Setup Time, STOP	0.6			µs

NOTE:
1. A device must internally provide a hold time of at least 300ns for the SDA signal (referred to the V_{IHMIN} of the SCLK signal) to bridge the undefined region of the falling edge of SCLK.
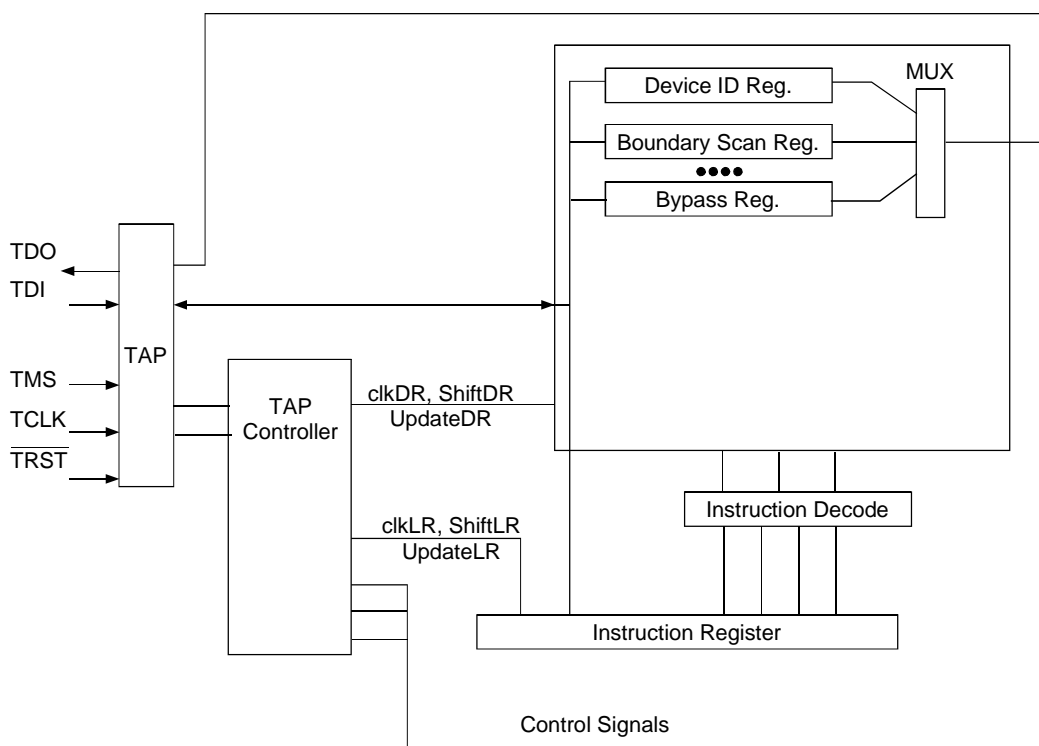
JTAG INTERFACE

Five additional pins (TDI, TDO, TMS, TCLK and $\overline{TRST}$) are provided to support the JTAG boundary scan interface. The IDT5T9891 incorporates the necessary tap controller and modified pad cells to implement the JTAG facility.

Note that IDT provides appropriate Boundary Scan Description Language program files for these devices.

The Standard JTAG interface consists of four basic elements:
- *Test Access Port (TAP)*
- *TAP controller*
- *Instruction Register (IR)*
- *Data Register Port (DR)*

The following sections provide a brief description of each element. For a complete description refer to the IEEE Standard Test Access Port Specification (IEEE Std. 1149.1-1990).


Boundary Scan Architecture

TEST ACCESS PORT (TAP)

The Tap interface is a general-purpose port that provides access to the internal of the processor. It consists of four input ports (TCLK, TMS, TDI, $\overline{TRST}$) and one output port (TDO).

THE TAP CONTROLLER

The Tap controller is a synchronous finite state machine that responds to TMS and TCLK signals to generate clock and control signals to the Instruction and Data Registers for capture and update of data.
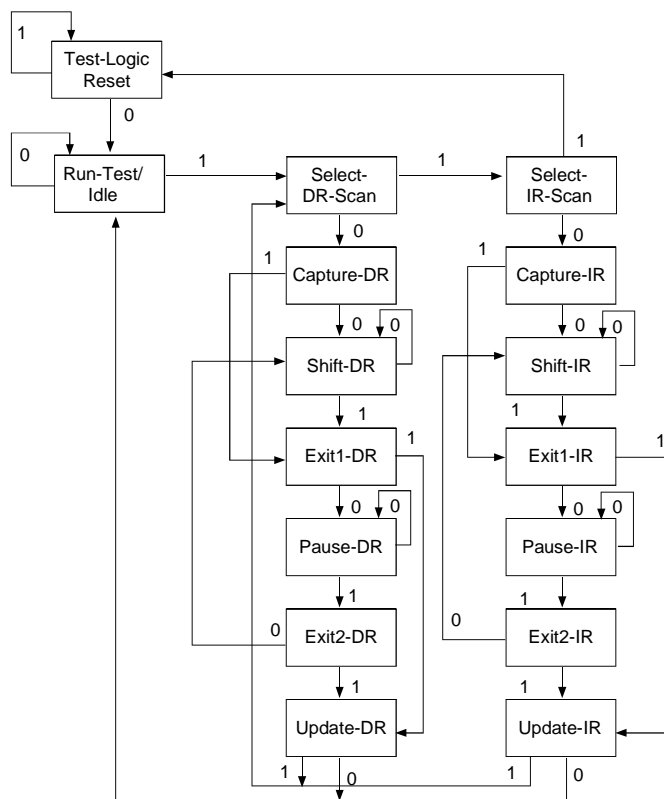
TAP Controller State Diagram

NOTES:
1. Five consecutive TCLK cycles with TMS = 1 will reset the TAP.
2. TAP controller must be reset before normal PLL operations can begin.

Refer to the IEEE Standard Test Access Port Specification (IEEE Std. 1149.1) for the full state diagram

All state transitions within the TAP controller occur at the rising edge of the TCLK pulse. The TMS signal level (0 or 1) determines the state progression that occurs on each TCLK rising edge. The TAP controller takes precedence over the PLL and must be reset after power up of the device. See $\overline{TRST}$ description for more details on TAP controller reset.

Test-Logic-Reset All test logic is disabled in this controller state enabling the normal operation of the IC. The TAP controller state machine is designed in such a way that, no matter what the initial state of the controller is, the Test-Logic-Reset state can be entered by holding TMS at high and pulsing TCLK five times. This is the reason why the Test Reset ($\overline{TRST}$) pin is optional.

Run-Test-Idle In this controller state, the test logic in the IC is active only if certain instructions are present. For example, if an instruction activates the self test, then it will be executed when the controller enters this state. The test logic in the IC is idles otherwise.

Select-DR-Scan This is a controller state where the decision to enter the Data Path or the Select-IR-Scan state is made.

Select-IR-Scan This is a controller state where the decision to enter the Instruction Path is made. The Controller can return to the Test-Logic-Reset state otherwise.

Capture-IR In this controller state, the shift register bank in the Instruction Register parallel loads a pattern of fixed values on the rising edge of TCLK. The last two significant bits are always required to be "01".

Shift-IR In this controller state, the instruction register gets connected between TDI and TDO, and the captured pattern gets shifted on each rising edge of TCLK. The instruction available on the TDI pin is also shifted in to the instruction register.

Exit1-IR This is a controller state where a decision to enter either the Pause-IR state or Update-IR state is made.

Pause-IR This state is provided in order to allow the shifting of instruction register to be temporarily halted.

Exit2-DR This is a controller state where a decision to enter either the Shift-IR state or Update-IR state is made.

Update-IR In this controller state, the instruction in the instruction register is latched in to the latch bank of the Instruction Register on every falling edge of TCLK. This instruction also becomes the current instruction once it is latched.

Capture-DR In this controller state, the data is parallel loaded in to the data registers selected by the current instruction on the rising edge of TCLK.

Shift-DR, Exit1-DR, Pause-DR, Exit2-DR and Update-DR These controller states are similar to the Shift-IR, Exit1-IR, Pause-IR, Exit2-IR and Update-IR states in the Instruction path.

THE INSTRUCTION REGISTER

The Instruction register allows an instruction to be shifted in serially into the processor at the rising edge of TCLK.

The Instruction is used to select the test to be performed, or the test data register to be accessed, or both. The instruction shifted into the register is latched at the completion of the shifting process when the TAP controller is at Update-IR state.

The instruction register must contain 4 bit instruction register-based cells which can hold instruction data. These mandatory cells are located nearest the serial outputs they are the least significant bits.

TEST DATA REGISTER

The Test Data register contains three test data registers: the Bypass, the Boundary Scan register and Device ID register.

These registers are connected in parallel between a common serial input and a common serial data output.

The following sections provide a brief description of each element. For a complete description, refer to the IEEE Standard Test Access Port Specification (IEEE Std. 1149.1-1990).

TEST BYPASS REGISTER

The register is used to allow test data to flow through the device from TDI to TDO. It contains a single stage shift register for a minimum length in serial path. When the bypass register is selected by an instruction, the shift register stage is set to a logic zero on the rising edge of TCLK when the TAP controller is in the Capture-DR state.

The operation of the bypass register should not have any effect on the operation of the device in response to the BYPASS instruction.

THE BOUNDARY-SCAN REGISTER

The Boundary Scan Register allows serial data TDI be loaded into or read out of the processor input/output ports. The Boundary Scan Register is a part of the IEEE 1149.1-1990 Standard JTAG Implementation.

THE DEVICE IDENTIFICATION REGISTER

The Device Identification Register is a Read Only 32-bit register used to specify the manufacturer, part number and version of the processor to be determined through the TAP in response to the IDCODE instruction.

IDT JEDEC ID number is 0xB3. This translates to 0x33 when the parity is dropped in the 11-bit Manufacturer ID field.

For the IDT5T9891, the Part Number field is 0X3A9.

JTAG DEVICE IDENTIFICATION REGISTER

31 (MSB)	28 27	12 11	1 0(LSB)
Version (4 bits) 0X0	Part number (16-bit)	Manufacturer ID (11-bit) 0X33	1

JTAG INSTRUCTION REGISTER

The Instruction register allows instruction to be serially input into the device when the TAP controller is in the Shift-IR state. The instruction is decoded to perform the following:

• Select test data registers that may operate while the instruction is current. The other test data registers should not interfere with chip operation and the selected data register.

• Define the serial test data register path that is used to shift data between TDI and TDO during data register scanning.

The Instruction Register is a 4-bit field (i.e.IR3, IR2, IR1, IR0) to decode sixteen different possible instructions. Instructions are decoded as follows.

JTAG INSTRUCTION REGISTER DECODING

IR (3)	IR (2)	IR (1)	IR (0)	Instruction	Function
0	0	0	0	EXTEST	Select boundary scan register
0	0	0	1	SAMPLE/PRELOAD	Select boundary scan register
0	0	1	0	IDCODE	Select chip identification data register
0	0	1	1		Reserved
0	1	0	0	PROGWRITE	Writing to the volatile programming registers
0	1	0	1	PROGREAD	Reading from the volatile programming registers
0	1	1	0	PROGSAVE	Saving the contents of the volatile programming registers to the EEPROM
0	1	1	1	PROGRESTORE	Loading the EEPROM contents into the volatile programming registers
1	0	0	0	CLAMP	JTAG
1	0	0	1	HIGHZ	JTAG
1	0	1	X	BYPASS	Select bypass register
1	1	X	X	BYPASS	Select bypass register

The following sections provide a brief description of each instruction. For a complete description refer to the IEEE Standard Test Access Port Specification (IEEE Std. 1149.1-1990).

EXTEST

The required EXTEST instruction places the IC into an external boundary-test mode and selects the boundary-scan register to be connected between TDI and TDO. During this instruction, the boundary-scan register is accessed to drive test data off-chip through the boundary outputs, and recieve test data off-chip through the boundary inputs. As such, the EXTEST instruction is the workhorse of IEEE. Std 1149.1, providing for probe-less testing of solder-joint opens/shorts and of logic cluster function.

SAMPLE/PRELOAD

The required SAMPLE/PRELOAD instruction allows the IC to remain in a normal functional mode and selects the boundary-scan register to be connected between TDI and TDO. During this instruction, the boundary-scan register can be accessed via a data scan operation, to take a sample of the functional data entering and leaving the IC.

IDCODE

The optional IDCODE instruction allows the IC to remain in its functional mode and selects the optional device identification register to be connected between TDI and TDO. The device identification register is a 32-bit shift register containing information regarding the IC manufacturer, device type, and version code. Accessing the device identification register does not interfere with the operation of the IC. Also, access to the device identification register should be immediately available, via a TAP data-scan operation, after power-up of the IC or after the TAP has been reset using the optional $\overline{TRST}$ pin or by otherwise moving to the Test-Logic-Reset state.

PROGWRITE

The PROGWRITE instruction is for writing the IDT5T9891 configuration data to the device's volatile programming registers. This instruction selects the programming register path for shifting data from TDI to TDO during data register scanning. The programming register path has 112 registers (14 bytes) between TDI and TDO. The 12 configuration data bytes are scanned in through TDI first, starting with Bit 0. After scanning in the last configuration bit, Bit 95, sixteen additional bits must be scanned in to place the configuration data in the proper location. The last sixteen registers in the programming path are reserved, read-only registers.

PROGREAD

The PROGREAD instruction is for reading out the IDT5T9891 configuration data from the device's volatile programming registers. This instruction selects the programming register path for shifting data from TDI to TDO during data register scanning. The programming register path has 112 registers between TDI and TDO, and the first bit scanned out through TDO will be Bit 0 of the configuration data.

PROGSAVE and PROGRESTORE (EEPROM OPERATION)

The PROGSAVE instruction is for copying the IDT5T9891 configuration data from the device's volatile programming registers to the EEPROM. This instruction selects the BYPASS register path for shifting data from TDI to TDO during data register scanning.

The PROGRESTORE instruction is for loading the IDT5T9891 configuration data from the EEPROM to the device's volatile programming registers. This instruction selects the BYPASS register path for shifting data from TDI to TDO during data register scanning.

During the execution of a PROGSAVE or PROGRESTORE instruction, the IDT5T9891 will not accept a new programming instruction (read, write, save, or restore). All non-programming JTAG instructions will function properly, but the user should wait until the save or restore is complete before issuing a new programming instruction. The time it takes for the save and restore instructions to complete depends on the PLL oscillator frequency, Fvco. The restore time, $T_{RESTORE}$, and the save time, T_{SAVE}, can be calculated as follows:

$$T_{RESTORE} = 1.23 \times 10^6 / F_{VCO} \qquad (mS)$$
$$T_{SAVE} = 3.09 \times 10^6 / F_{VCO} + 52 \qquad (mS)$$

If a new programming instruction is issued before the save or restore completes, the new instruction is ignored, and the BYPASS register path remains in effect for shifting data from TDI to TDO during data register scanning.

In order for the ProgSave and ProgRestore instructions to function properly, the IDT5T9890 must not be in power-down mode ($\overline{PD}$ must be HIGH), and the PLL must be enabled ($\overline{PLL\_EN}$ = LOW and Bit 57 = 0).

On power-up of the IDT5T9891, an automatic restore is performed to load the EEPROM contents into the internal programming registers. The auto-restore will not function properly if the device is in power-down mode ($\overline{PD}$ must be HIGH). The device's auto-restore feature will function regardless of the state of the $\overline{PLL\_EN}$ pin or Bit 57. The time it takes for the device to complete the auto-restore is approximately 3ms.

CLAMP

The optional CLAMP instruction loads the contents from the boundary-scan register onto the outputs of the IC, and selects the one-bit bypass register to be connected between TDI and TDO. During this instruction, data can be shifted through the bypass register from TDI to TDO without affecting the condition of the IC outputs.

HIGH-IMPEDANCE

The optional High-Impedance instruction sets all outputs (including two-state as well as three-state types) of an IC to a disabled (high-impedance) state and selects the one-bit bypass register to be connected between TDI and TDO. During this instruction, data can be shifted through the bypass register from TDI to TDO without affecting the condition of the IC outputs.

BYPASS

The required BYPASS instruction allows the IC to remain in a normal functional mode and selects the one-bit bypass register to be connected between TDI and TDO. The BYPASS instruction allows serial data to be transferred through the IC from TDI to TDO without affecting the operation of the IC.

PROGRAMMING NOTES

Once the IDT5T9891 has been programmed either with a ProgWrite or ProgRestore instruction, the device will attempt to achieve phase lock using the new PLL configuration. If there is a valif REF and FB input clock connected to the device, and it does not achieve lock, the user should issue a ProgRead instruction to confirm that the PLL configuration data is valid.

On power-up and before the automatic ProgRestore instruction has completed, the internal programming registers will contain the value of '0' for all bits 95:0. The PLL will remain at the minimum frequency and will not achieve phase lock until after the automatic restore is completed. If the outputs are enabled by the nSOE pins, the outputs will toggle at the minimum frequency. If the outputs are disabled by the nSOE pins, and the OMODE pin is set high, the nQ[1:0] and QFB are stopped HIGH, while QFB is stopped LOW.
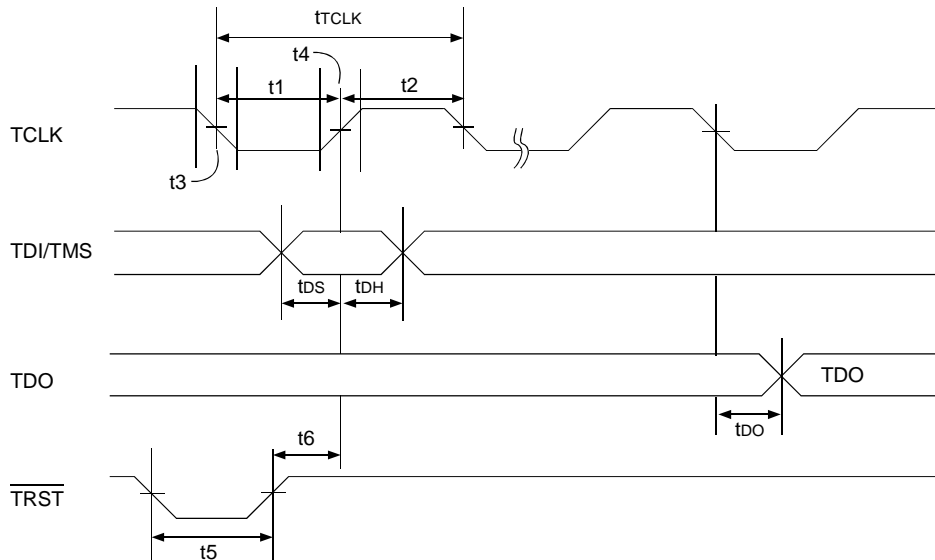
Standard JTAG Timing

NOTE:

t1 = $t_{TCLKLOW}$

t2 = $t_{TCLKHIGH}$

t3 = $t_{TCLKFALL}$

t4 = $t_{TCLKRISE}$

t5 = t_{RST} (reset pulse width)

t6 = t_{RSR} (reset recovery)

JTAG
AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Min.	Max.	Units
t_{TCLK}	JTAG Clock Input Period	100	—	ns
$t_{TCLKHIGH}$	JTAG Clock HIGH	40	—	ns
$t_{TCLKLOW}$	JTAG Clock Low	40	—	ns
$t_{TCLKRISE}$	JTAG Clock Rise Time	—	5[1]	ns
$t_{TCLKFALL}$	JTAG Clock Fall Time	—	5[1]	ns
t_{RST}	JTAG Reset	50	—	ns
t_{RSR}	JTAG Reset Recovery	50	—	ns

NOTE:
1. Guaranteed by design.

SYSTEM INTERFACE PARAMETERS

Symbol	Parameter	Min.	Max.	Units
t_{DO}	Data Output[1]	—	20	ns
t_{DOH}	Data Output Hold[1]	0	—	ns
t_{DS}	Data Input, t_{RISE} = 3ns	10	—	ns
t_{DH}	Data Input, t_{FALL} = 3ns	10	—	ns

NOTE:
1. 50pF loading on external output signals.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Test Conditions		Min.	Max	Unit
V_{IHH}	Input HIGH Voltage Level[1]	3-Level Inputs Only		$V_{DD} - 0.4$	—	V
V_{IMM}	Input MID Voltage Level[1]	3-Level Inputs Only		$V_{DD}/2 - 0.2$	$V_{DD}/2 + 0.2$	V
V_{ILL}	Input LOW Voltage Level[1]	3-Level Inputs Only		—	0.4	V
I_3	3-Level Input DC Current (ADDR0, ADDR1)	$V_{IN} = V_{DD}$	HIGH Level	—	200	μA
		$V_{IN} = V_{DD}/2$	MID Level	–50	+50	
		$V_{IN} = GND$	LOW Level	–200	—	
I_{PU}	Input Pull-Up Current	V_{DD} = Max., $V_{IN} = GND$		–100	—	μA

NOTE:

1. These inputs are normally wired to V_{DD}, GND, or left floating. Internal termination resistors bias unconnected inputs to $V_{DD}/2$. If these inputs are switched dynamically after powerup, the function and timing of the outputs may be glitched, and the PLL may require additional t_{LOCK} time before all datasheet limits are achieved.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE FOR HSTL[1]

Symbol	Parameter	Test Conditions	Min.	Typ.[7]	Max	Unit
Input Characteristics						
I_{IH}	Input HIGH Current	V_{DD} = 2.7V $\quad$ V_I = V_{DDQN}/GND	—	—	±5	µA
I_{IL}	Input LOW Current	V_{DD} = 2.7V $\quad$ V_I = GND/V_{DDQN}	—	—	±5	
V_{IK}	Clamp Diode Voltage	V_{DD} = 2.3V, I_{IN} = -18mA	—	- 0.7	- 1.2	V
V_{IN}	DC Input Voltage		- 0.3		+3.6	V
V_{DIF}	DC Differential Voltage[2,8]		0.2		—	V
V_{CM}	DC Common Mode Input Voltage[3,8]		680	750	900	mV
V_{IH}	DC Input HIGH[4,5,8]		V_{REF} + 100		—	mV
V_{IL}	DC Input LOW[4,6,8]		—		V_{REF} - 100	mV
V_{REF}	Single-Ended Reference Voltage[4,8]		—	750	—	mV
Output Characteristics						
V_{OH}	Output HIGH Voltage	I_{OH} = -8mA	V_{DDQN} - 0.4		—	V
		I_{OH} = -100µA	V_{DDQN} - 0.1		—	
V_{OL}	Output LOW Voltage	I_{OL} = 8mA	—		0.4	V
		I_{OL} = 100µA	—		0.1	
V_{OX}	nQ/nQ̄ and FB/FB̄ Output Crossing Point		V_{DDQN}/2 - 150	V_{DDQN}/2	V_{DDQN}/2 + 150	mV

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. V_{DIF} specifies the minimum input differential voltage (V_{TR} - V_{CP}) required for switching where V_{TR} is the "true" input level and V_{CP} is the "complement" input level. Differential mode only. The DC differential voltage must be maintained to guarantee retaining the existing HIGH or LOW input. The AC differential voltage must be achieved to guarantee switching to a new state.

3. V_{CM} specifies the maximum allowable range of (V_{TR} + V_{CP}) /2. Differential mode only.

4. For single-ended operation, in differential mode, REF̄[1:0]/$V_{REF[1:0]}$ is tied to the DC voltage $V_{REF[1:0]}$.

5. Voltage required to maintain a logic HIGH, single-ended operation in differential mode.

6. Voltage required to maintain a logic LOW, single-ended operation in differential mode.

7. Typical values are at V_{DD} = 2.5V, V_{DDQN} = 1.5V, +25°C ambient.

8. The reference clock input is capable of HSTL, eHSTL, LVEPECL, 1.8V or 2.5V LVTTL operation independent of the device output. (See Input/Output Selection table.)

POWER SUPPLY CHARACTERISTICS FOR HSTL OUTPUTS[1]

Symbol	Parameter	Test Conditions[2]	Typ.	Max	Unit
I_{DDQ}	Quiescent V_{DD} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	112	150	mA
I_{DDQQ}	Quiescent V_{DDQN} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	2	75	µA
I_{DDPD}	Power Down Current	V_{DD} = Max., $\overline{PD}$ = LOW, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH	0.3	3	mA
I_{DDD}	Dynamic V_{DD} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	22	30	µA/MHz
I_{DDDQ}	Dynamic V_{DDQN} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	19	30	µA/MHz
I_{TOT}	Total Power V_{DD} Supply Current[4,5]	V_{DDQN} = 1.5V, F_{VCO} = 100MHz, C_L = 15pF	280	400	mA
		V_{DDQN} = 1.5V, F_{VCO} = 250MHz, C_L = 15pF	320	450	
I_{TOTQ}	Total Power V_{DDQN} Supply Current[4,5]	V_{DDQN} = 1.5V, F_{VCO} = 100MHz, C_L = 15pF	130	200	mA
		V_{DDQN} = 1.5V, F_{VCO} = 250MHz, C_L = 15pF	220	330	

NOTES:

1. These power consumption characteristics are for all the valid input interfaces and cover the worst case input and output interface combinations.

2. The termination resistors are excluded from these measurements.

3. If the differential input interface is used, the true input is held LOW and the complementary input is held HIGH.

4. Bit 60 = 1.

5. All outputs are at the same interface level.

DIFFERENTIAL INPUT AC TEST CONDITIONS FOR HSTL

Symbol	Parameter	Value	Units
V_{DIF}	Input Signal Swing[1]	1	V
V_X	Differential Input Signal Crossing Point[2]	750	mV
V_{THI}	Input Timing Measurement Reference Level[3]	Crossing Point	V
t_R, t_F	Input Signal Edge Rate[4]	1	V/ns

NOTES:

1. The 1V peak-to-peak input pulse level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_{DIF} (AC) specification under actual use conditions.

2. A 750mV crossing point level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_X specification under actual use conditions.

3. In all cases, input waveform timing is marked at the differential cross-point of the input signals.

4. The input signal edge rate of 1V/ns or greater is to be maintained in the 20% to 80% range of the input waveform.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE FOR eHSTL[1]

Symbol	Parameter	Test Conditions		Min.	Typ.[7]	Max	Unit
Input Characteristics							
I_{IH}	Input HIGH Current	V_{DD} = 2.7V	V_I = V_{DDQN}/GND	—	—	±5	µA
I_{IL}	Input LOW Current	V_{DD} = 2.7V	V_I = GND/V_{DDQN}	—	—	±5	
V_{IK}	Clamp Diode Voltage	V_{DD} = 2.3V, I_{IN} = -18mA		—	- 0.7	- 1.2	V
V_{IN}	DC Input Voltage			- 0.3		+3.6	V
V_{DIF}	DC Differential Voltage[2,8]			0.2		—	V
V_{CM}	DC Common Mode Input Voltage[3,8]			800	900	1000	mV
V_{IH}	DC Input HIGH[4,5,8]			V_{REF} + 100		—	mV
V_{IL}	DC Input LOW[4,6,8]			—		V_{REF} - 100	mV
V_{REF}	Single-Ended Reference Voltage[4,8]			—	900	—	mV
Output Characteristics							
V_{OH}	Output HIGH Voltage	I_{OH} = -8mA		V_{DDQN} - 0.4		—	V
		I_{OH} = -100µA		V_{DDQN} - 0.1		—	V
V_{OL}	Output LOW Voltage	I_{OL} = 8mA		—		0.4	V
		I_{OL} = 100µA		—		0.1	V
V_{OX}	nQ/nQ̄ and FB/FB̄ Output Crossing Point			V_{DDQN}/2 - 150	V_{DDQN}/2	V_{DDQN}/2 + 150	mV

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. V_{DIF} specifies the minimum input differential voltage (V_{TR} - V_{CP}) required for switching where V_{TR} is the "true" input level and V_{CP} is the "complement" input level. Differential mode only. The DC differential voltage must be maintained to guarantee retaining the existing HIGH or LOW input. The AC differential voltage must be achieved to guarantee switching to a new state.

3. V_{CM} specifies the maximum allowable range of (V_{TR} + V_{CP}) /2. Differential mode only.

4. For single-ended operation, in a differential mode, REF̄[1:0]/$V_{REF[1:0]}$ is tied to the DC voltage $V_{REF[1:0]}$.

5. Voltage required to maintain a logic HIGH, single-ended operation in differential mode.

6. Voltage required to maintain a logic LOW, single-ended operation in differential mode.

7. Typical values are at V_{DD} = 2.5V, V_{DDQN} = 1.8V, +25°C ambient.

8. The reference clock input is capable of HSTL, eHSTL, LVEPECL, 1.8V or 2.5V LVTTL operation independent of the device output. (See Input/Output Selection table.)

POWER SUPPLY CHARACTERISTICS FOR eHSTL OUTPUTS[1]

Symbol	Parameter	Test Conditions[2]	Typ.	Max	Unit
I_{DDQ}	Quiescent V_{DD} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	112	150	mA
I_{DDQQ}	Quiescent V_{DDQN} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	2	75	μA
I_{DDPD}	Power Down Current	V_{DD} = Max., $\overline{PD}$ = LOW, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH	0.3	3	mA
I_{DDD}	Dynamic V_{DD} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	22	30	μA/MHz
I_{DDDQ}	Dynamic V_{DDQN} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	22	30	μA/MHz
I_{TOT}	Total Power V_{DD} Supply Current[4,5]	V_{DDQN} = 1.8V, F_{VCO} = 100MHz, C_L = 15pF	280	400	mA
		V_{DDQN} = 1.8V, F_{VCO} = 250MHz, C_L = 15pF	330	450	
I_{TOTQ}	Total Power V_{DDQN} Supply Current[4,5]	V_{DDQN} = 1.8V, F_{VCO} = 100MHz, C_L = 15pF	160	250	mA
		V_{DDQN} = 1.8V, F_{VCO} = 250MHz, C_L = 15pF	270	400	

NOTES:

1. These power consumption characteristics are for all the valid input interfaces and cover the worst case input and output interface combinations.

2. The termination resistors are excluded from these measurements.

3. If the differential input interface is used, the true input is held LOW and the complementary input is held HIGH.

4. Bit 60 = 1.

5. All outputs are at the same interface level.

DIFFERENTIAL INPUT AC TEST CONDITIONS FOR eHSTL

Symbol	Parameter	Value	Units
V_{DIF}	Input Signal Swing[1]	1	V
V_X	Differential Input Signal Crossing Point[2]	900	mV
V_{THI}	Input Timing Measurement Reference Level[3]	Crossing Point	V
t_R, t_F	Input Signal Edge Rate[4]	1	V/ns

NOTES:

1. The 1V peak-to-peak input pulse level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_{DIF} (AC) specification under actual use conditions.

2. A 900mV crossing point level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_X specification under actual use conditions.

3. In all cases, input waveform timing is marked at the differential cross-point of the input signals.

4. The input signal edge rate of 1V/ns or greater is to be maintained in the 20% to 80% range of the input waveform.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE FOR LVEPECL[1]

Symbol	Parameter	Test Conditions	Min.	Typ.[2]	Max	Unit
Input Characteristics						
I_{IH}	Input HIGH Current	V_{DD} = 2.7V $\quad$ V_I = V_{DDQN}/GND	—	—	±5	µA
I_{IL}	Input LOW Current	V_{DD} = 2.7V $\quad$ V_I = GND/V_{DDQN}	—	—	±5	
V_{IK}	Clamp Diode Voltage	V_{DD} = 2.3V, I_{IN} = -18mA	—	- 0.7	- 1.2	V
V_{IN}	DC Input Voltage		- 0.3	—	3.6	V
V_{CM}	DC Common Mode Input Voltage[3,5]		915	1082	1248	mV
V_{REF}	Single-Ended Reference Voltage[4,5]		—	1082	—	mV
V_{IH}	DC Input HIGH		1275	—	1620	mV
V_{IL}	DC Input LOW		555	—	875	mV

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. Typical values are at V_{DD} = 2.5V, +25°C ambient.

3. V_{CM} specifies the maximum allowable range of (V_{TR} + V_{CP}) /2. Differential mode only.

4. For single-ended operation while in differential mode, $\overline{REF}_{[1:0]}$/$V_{REF[1:0]}$ is tied to the DC voltage $V_{REF[1:0]}$.

5. The reference clock input is capable of HSTL, eHSTL, LVEPECL, 1.8V or 2.5V LVTTL operation independent of the device output. (See Input/Output Selection table.)

DIFFERENTIAL INPUT AC TEST CONDITIONS FOR LVEPECL

Symbol	Parameter	Value	Units
V_{DIF}	Input Signal Swing[1]	732	mV
V_X	Differential Input Signal Crossing Point[2]	1082	mV
V_{THI}	Input Timing Measurement Reference Level[3]	Crossing Point	V
t_R, t_F	Input Signal Edge Rate[4]	1	V/ns

NOTES:

1. The 732mV peak-to-peak input pulse level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_{DIF} (AC) specification under actual use conditions.

2. A 1082mV crossing point level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_X specification under actual use conditions.

3. In all cases, input waveform timing is marked at the differential cross-point of the input signals.

4. The input signal edge rate of 1V/ns or greater is to be maintained in the 20% to 80% range of the input waveform.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE FOR 2.5V LVTTL[1]

Symbol	Parameter	Test Conditions	Min.	Typ.[8]	Max	Unit
Input Characteristics						
I_{IH}	Input HIGH Current	V_{DD} = 2.7V V_I = V_{DDQN}/GND	—	—	±5	μA
I_{IL}	Input LOW Current	V_{DD} = 2.7V V_I = GND/V_{DDQN}	—	—	±5	
V_{IK}	Clamp Diode Voltage	V_{DD} = 2.3V, I_{IN} = -18mA	—	- 0.7	- 1.2	V
V_{IN}	DC Input Voltage		- 0.3		+3.6	V
Single-Ended Inputs[2]						
V_{IH}	DC Input HIGH		1.7		—	V
V_{IL}	DC Input LOW		—		0.7	V
Differential Inputs						
V_{DIF}	DC Differential Voltage[3,9]		0.2		—	V
V_{CM}	DC Common Mode Input Voltage[4,9]		1150	1250	1350	mV
V_{IH}	DC Input HIGH[5,6,9]		V_{REF} + 100		—	mV
V_{IL}	DC Input LOW[5,7,9]		—		V_{REF} - 100	mV
V_{REF}	Single-Ended Reference Voltage[5,9]		—	1250	—	mV
Output Characteristics						
V_{OH}	Output HIGH Voltage	I_{OH} = -12mA	V_{DDQN} - 0.4		—	V
		I_{OH} = -100μA	V_{DDQN} - 0.1		—	V
V_{OL}	Output LOW Voltage	I_{OL} = 12mA	—		0.4	V
		I_{OL} = 100μA	—		0.1	V

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. For 2.5V LVTTL single-ended operation, Bits 35/34, 33/32, 31/30 = 0/1 or 1/0, and $\overline{REF}$[1:0]/V_{REF}[1:0] is left floating. If Bits 47 - 36 = 0, $\overline{FB}$/V_{REF2} should be left floating.

3. V_{DIF} specifies the minimum input differential voltage (V_{TR} - V_{CP}) required for switching where V_{TR} is the "true" input level and V_{CP} is the "complement" input level. Differential mode only. The DC differential voltage must be maintained to guarantee retaining the existing HIGH or LOW input. The AC differential voltage must be achieved to guarantee switching to a new state.

4. V_{CM} specifies the maximum allowable range of (V_{TR} + V_{CP}) /2. Differential mode only.

5. For single-ended operation, in differential mode, $\overline{REF}$[1:0]/V_{REF}[1:0] is tied to the DC voltage V_{REF}[1:0].

6. Voltage required to maintain a logic HIGH, single-ended operation in differential mode.

7. Voltage required to maintain a logic LOW, single-ended operation in differential mode.

8. Typical values are at V_{DD} = 2.5V, V_{DDQN} = V_{DD}, +25°C ambient.

9. The reference clock input is capable of HSTL, eHSTL, LVEPECL, 1.8V or 2.5V LVTTL operation independent of the device output. (See Input/Output Selection table.)

POWER SUPPLY CHARACTERISTICS FOR 2.5V LVTTL OUTPUTS[1]

Symbol	Parameter	Test Conditions[2]	Typ.	Max	Unit
I_{DDQ}	Quiescent V_{DD} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	112	150	mA
I_{DDQQ}	Quiescent V_{DDQN} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	15	75	μA
I_{DDPD}	Power Down Current	V_{DD} = Max., $\overline{PD}$ = LOW, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH	0.3	3	mA
I_{DDD}	Dynamic V_{DD} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	21	30	μA/MHz
I_{DDDQ}	Dynamic V_{DDQN} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	33	40	μA/MHz
I_{TOT}	Total Power V_{DD} Supply Current[4,5]	V_{DDQN} = 2.5V., F_{VCO} = 100MHz, C_L = 15pF	280	400	mA
		V_{DDQN} = 2.5V., F_{VCO} = 250MHz, C_L = 15pF	320	450	
I_{TOTQ}	Total Power V_{DDQN} Supply Current[4,5]	V_{DDQN} = 2.5V., F_{VCO} = 100MHz, C_L = 15pF	210	320	mA
		V_{DDQN} = 2.5V., F_{VCO} = 250MHz, C_L = 15pF	345	530	

NOTES:

1. These power consumption characteristics are for all the valid input interfaces and cover the worst case input and output interface combinations.

2. The termination resistors are excluded from these measurements.

3. If the differential input interface is used, the true input is held LOW and the complementary input is held HIGH.

4. Bit 60 = 1.

5. All outputs are at the same interface level.

DIFFERENTIAL INPUT AC TEST CONDITIONS FOR 2.5V LVTTL

Symbol	Parameter	Value	Units
V_{DIF}	Input Signal Swing[1]	V_{DD}	V
V_X	Differential Input Signal Crossing Point[2]	$V_{DD}/2$	V
V_{THI}	Input Timing Measurement Reference Level[3]	Crossing Point	V
t_R, t_F	Input Signal Edge Rate[4]	2.5	V/ns

NOTES:

1. A nominal 2.5V peak-to-peak input pulse level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_{DIF} (AC) specification under actual use conditions.

2. A nominal 1.25V crossing point level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_X specification under actual use conditions.

3. In all cases, input waveform timing is marked at the differential cross-point of the input signals.

4. The input signal edge rate of 2.5V/ns or greater is to be maintained in the 20% to 80% range of the input waveform.

SINGLE-ENDED INPUT AC TEST CONDITIONS FOR 2.5V LVTTL

Symbol	Parameter	Value	Units
V_{IH}	Input HIGH Voltage	V_{DD}	V
V_{IL}	Input LOW Voltage	0	V
V_{THI}	Input Timing Measurement Reference Level[1]	$V_{DD}/2$	V
t_R, t_F	Input Signal Edge Rate[2]	2	V/ns

NOTES:

1. A nominal 1.25V timing measurement reference level is specified to allow constant, repeatable results in an automatic test equipment (ATE) environment.

2. The input signal edge rate of 2V/ns or greater is to be maintained in the 10% to 90% range of the input waveform.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE FOR 1.8V LVTTL[1]

Symbol	Parameter	Test Conditions		Min.	Typ.[8]	Max	Unit
Input Characteristics							
I_{IH}	Input HIGH Current	V_{DD} = 2.7V	V_I = V_{DDQN}/GND	—	—	±5	µA
I_{IL}	Input LOW Current	V_{DD} = 2.7V	V_I = GND/V_{DDQN}	—	—	±5	
V_{IK}	Clamp Diode Voltage	V_{DD} = 2.3V, I_{IN} = -18mA		—	- 0.7	- 1.2	V
V_{IN}	DC Input Voltage			- 0.3		V_{DDQN} + 0.3	V
Single-Ended Inputs[2]							
V_{IH}	DC Input HIGH			1.073[10]		—	V
V_{IL}	DC Input LOW			—		0.683[11]	V
Differential Inputs							
V_{DIF}	DC Differential Voltage[3,9]			0.2		—	V
V_{CM}	DC Common Mode Input Voltage[4,9]			825	900	975	mV
V_{IH}	DC Input HIGH[5,6,9]			V_{REF} + 100		—	mV
V_{IL}	DC Input LOW[5,7,9]			—		V_{REF} - 100	mV
V_{REF}	Single-Ended Reference Voltage[5,9]			—	900	—	mV
Output Characteristics							
V_{OH}	Output HIGH Voltage	I_{OH} = -6mA		V_{DDQN} - 0.4		—	V
		I_{OH} = -100µA		V_{DDQN} - 0.1		—	V
V_{OL}	Output LOW Voltage	I_{OL} = 6mA		—		0.4	V
		I_{OL} = 100µA		—		0.1	V

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. For 1.8V LVTTL single-ended operation, Bits 35 - 30 = 0 and $\overline{REF}_{[1:0]}$/$V_{REF[1:0]}$ is left floating. If Bits 47/46, 45/44, 43/42, 41/40, 39/38, 37/36 = 0/1, $\overline{FB}$/V_{REF2} should be left floating.

3. V_{DIF} specifies the minimum input differential voltage (V_{TR} - V_{CP}) required for switching where V_{TR} is the "true" input level and V_{CP} is the "complement" input level. Differential mode only. The DC differential voltage must be maintained to guarantee retaining the existing HIGH or LOW input. The AC differential voltage must be achieved to guarantee switching to a new state.

4. V_{CM} specifies the maximum allowable range of (V_{TR} + V_{CP}) /2. Differential mode only.

5. For single-ended operation in differential mode, $\overline{REF}_{[1:0]}$/$V_{REF[1:0]}$ is tied to the DC voltage $V_{REF[1:0]}$. The input is guaranteed to toggle within ±200mV of $V_{REF[1:0]}$ when $V_{REF[1:0]}$ is constrained within +600mV and V_{DDI}-600mV, where V_{DDI} is the nominal 1.8V power supply of the device driving the $REF_{[1:0]}$ input. To guarantee switching in voltage range specified in the JEDEC 1.8V LVTTL interface specification, $V_{REF[1:0]}$ must be maintained at 900mV with appropriate tolerances.

6. Voltage required to maintain a logic HIGH, single-ended operation in differential mode.

7. Voltage required to maintain a logic LOW, single-ended operation in differential mode.

8. Typical values are at V_{DD} = 2.5V, V_{DDQN} = 1.8V, +25°C ambient.

9. The reference clock input is capable of HSTL, eHSTL, LVEPECL, 1.8V or 2.5V LVTTL operation independent of the device output. (See Input/Output Selection table.)

10. This value is the worst case minimum V_{IH} over the specification range of the 1.8V power supply. The 1.8V LVTTL specification is V_{IH} = 0.65 * V_{DD} where V_{DD} is 1.8V ± 0.15V. However, the LVTTL translator is supplied by a 2.5V nominal supply on this part. To ensure compliance with the specification, the translator was designed to accept the calculated worst case value (V_{IH} = 0.65 * [1.8 - 0.15V]) rather than reference against a nominal 1.8V supply.

11. This value is the worst case maximum V_{IL} over the specification range of the 1.8V power supply. The 1.8V LVTTL specification is V_{IL} = 0.35 * V_{DD} where V_{DD} is 1.8V ± 0.15V. However, the LVTTL translator is supplied by a 2.5V nominal supply on this part. To ensure compliance with the specification, the translator was designed to accept the calculated worst case value (V_{IL} = 0.35 * [1.8 + 0.15V]) rather than reference against a nominal 1.8V supply.

POWER SUPPLY CHARACTERISTICS FOR 1.8V LVTTL OUTPUTS[1]

Symbol	Parameter	Test Conditions[2]	Typ.	Max	Unit
I_{DDQ}	Quiescent V_{DD} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	112	150	mA
I_{DDQQ}	Quiescent V_{DDQN} Power Supply Current[3]	V_{DDQN} = Max., REF = LOW, $\overline{PD}$ = HIGH, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH, Outputs enabled, All outputs unloaded	2	75	μA
I_{DDPD}	Power Down Current	V_{DD} = Max., $\overline{PD}$ = LOW, $\overline{nSOE}$ = LOW, $\overline{PLL\_EN}$ = HIGH	0.3	3	mA
I_{DDD}	Dynamic V_{DD} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	19	30	μA/MHz
I_{DDDQ}	Dynamic V_{DDQN} Power Supply Current per Output	V_{DD} = Max., V_{DDQN} = Max., C_L = 0pF	22	30	μA/MHz
I_{TOT}	Total Power V_{DD} Supply Current[4,5]	V_{DDQN} = 1.8V., F_{VCO} = 100MHz, C_L = 15pF	275	400	mA
		V_{DDQN} = 1.8V., F_{VCO} = 250MHz, C_L = 15pF	310	450	
I_{TOTQ}	Total Power V_{DDQN} Supply Current[4,5]	V_{DDQN} = 1.8V., F_{VCO} = 100MHz, C_L = 15pF	135	200	mA
		V_{DDQN} = 1.8V., F_{VCO} = 250MHz, C_L = 15pF	200	300	

NOTES:

1. These power consumption characteristics are for all the valid input interfaces and cover the worst case input and output interface combinations.

2. The termination resistors are excluded from these measurements.

3. If the differential input interface is used, the true input is held LOW and the complementary input is held HIGH.

4. Bit 60 = 1.

5. All outputs are at the same interface level.

DIFFERENTIAL INPUT AC TEST CONDITIONS FOR 1.8V LVTTL

Symbol	Parameter	Value	Units
V_{DIF}	Input Signal Swing[1]	V_{DDI}	V
V_X	Differential Input Signal Crossing Point[2]	$V_{DDI}/2$	mV
V_{THI}	Input Timing Measurement Reference Level[3]	Crossing Point	V
t_R, t_F	Input Signal Edge Rate[4]	1.8	V/ns

NOTES:

1. V_{DDI} is the nominal 1.8V supply (1.8V ± 0.15V) of the part or source driving the input. A nominal 1.8V peak-to-peak input pulse level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_{DIF} (AC) specification under actual use conditions.

2. A nominal 900mV crossing point level is specified to allow consistent, repeatable results in an automatic test equipment (ATE) environment. This device meets the V_X specification under actual use conditions.

3. In all cases, input waveform timing is marked at the differential cross-point of the input signals.

4. The input signal edge rate of 1.8V/ns or greater is to be maintained in the 20% to 80% range of the input waveform.

SINGLE-ENDED INPUT AC TEST CONDITIONS FOR 1.8V LVTTL

Symbol	Parameter	Value	Units
V_{IH}	Input HIGH Voltage[1]	V_{DDI}	V
V_{IL}	Input LOW Voltage	0	V
V_{THI}	Input Timing Measurement Reference Level[2]	$V_{DDI}/2$	mV
t_R, t_F	Input Signal Edge Rate[3]	2	V/ns

NOTES:

1. V_{DDI} is the nominal 1.8V supply (1.8V ± 0.15V) of the part or source driving the input.

2. A nominal 900mV timing measurement reference level is specified to allow constant, repeatable results in an automatic test equipment (ATE) environment.

3. The input signal edge rate of 2V/ns or greater is to be maintained in the 10% to 90% range of the input waveform.

AC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

All outputs at the same interface level

Symbol	Parameter		Min.	Typ.	Max	Unit
F_{NOM}	VCO Frequency Range		see JTAG/I²C Serial Configurations: VCO Frequency Range table			
t_{RPW}	Reference Clock Pulse Width HIGH or LOW		1	—	—	ns
t_{FPW}	Feedback Input Pulse Width HIGH or LOW		1	—	—	ns
t_U	Programmable Skew Time Unit		see Control Summary Table			
$t_{SK(O)}$	Output Skew (Rise-Rise, Fall-Fall, Nominal)[1,2]		—	—	100	ps
$t_{SK1(\omega)}$	Multiple Frequency Skew (Rise-Rise, Fall-Fall, Nominal-Divided, Divided-Divided)[1,2,3]		—	—	100	ps
$t_{SK2(\omega)}$	Multiple Frequency Skew (Rise-Fall, Nominal-Divided, Divided-Divided)[1,2,3]		—	—	300	ps
$t_{SK1(INV)}$	Inverting Skew (Nominal-Inverted)[1,2]		—	—	300	ps
$t_{SK2(INV)}$	Inverting Skew (Rise-Rise, Fall-Fall, Rise-Fall, Inverted-Divided)[1,2,3]		—	—	300	ps
$t_{SK(PR)}$	Process Skew[1,2,4]		—	—	300	ps
$t_{(\phi)}$	REF Input to FB Static Phase Offset[5]		-100	—	100	ps
t_{ODCV}	Output Duty Cycle Variation from 50%[11,12]	1.8V LVTTL	-375	—	375	ps
		2.5V LVTTL	-275	—	275	
t_{ORISE}	Output Rise Time[6]	HSTL / eHSTL / 1.8V LVTTL	—	—	1.2	ns
		2.5V LVTTL	—	—	1	
t_{OFALL}	Output Fall Time[6]	HSTL / eHSTL / 1.8V LVTTL	—	—	1.2	ns
		2.5V LVTTL	—	—	1	
t_L	Power-up PLL Lock Time[7]		—	—	4	ms
$t_{L(\omega)}$	PLL Lock Time After Input Frequency Change[7]		—	—	1	ms
$t_{L(PD)}$	PLL Lock Time After Asserting $\overline{PD}$ Pin[7]		—	—	1	ms
$t_{L(REFSEL1)}$	PLL Lock Time After Change in REF_SEL[7,9]		—	—	100	μs
$t_{L(REFSEL2)}$	PLL Lock Time After Change in REF_SEL (REF1 and REF0 are different frequency)[7]		—	—	1	ms
$t_{JIT(CC)}$	Cycle-to-Cycle Output Jitter (peak-to-peak)[2,8]		—	50	75	ps
$t_{JIT(PER)}$	Period Jitter (peak-to-peak)[2,8]		—	—	75	ps
$t_{JIT(HP)}$	Half Period Jitter (peak-to-peak)[2,8,10]		—	—	125	ps
$t_{JIT(DUTY)}$	Duty Cycle Jitter (peak-to-peak)[2,8]		—	—	100	ps
V_{OX}	HSTL and eHSTL Differential True and Complementary Output Crossing Voltage Level		$V_{DDQN}/2 - 150$	$V_{DDQN}/2$	$V_{DDQN}/2 + 150$	mV

NOTES:

1. Skew is the time between the earliest and latest output transition among all outputs for which the same t_U delay has been selected, when all outputs are loaded with the specified load.
2. For differential LVTTL outputs, the measurement is made at $V_{DDQN}/2$, where the true outputs are only compared with other true outputs and the complementary outputs are only compared to other complementary outputs. For differential HSTL/eHSTL outputs, the measurement is made at the crossing point (V_{OX}) of the true and complementary signals.
3. There are three classes of outputs: nominal (multiple of t_U delay), inverted, and divided (divide-by-2 or divide-by-4 mode).
4. $t_{SK(PR)}$ is the output to corresponding output skew between any two devices operating under the same conditions (V_{DD} and V_{DDON}, ambient temperature, air flow, etc.).
5. $t_{(\phi)}$ is measured with REF and FB the same type of input, the same rise and fall times. For 1.8V / 2.5V LVTTL input and output, the measurement is taken from V_{THI} on REF to V_{THI} on FB. For HSTL / eHSTL input and output, the measurement is taken from the crosspoint of REF/$\overline{REF}$ to the crosspoint of FB/$\overline{FB}$. All outputs are set to 0t_U, FB input divider is set to divide-by-one, and Bit 60 = 1.
6. Output rise and fall times are measured between 20% to 80% of the actual output voltage swing.
7. t_L, $t_{L(\omega)}$, $t_{L(REFSEL1)}$, $t_{L(REFSEL2)}$, and $t_{L(PD)}$ are the times that are required before the synchronization is achieved. These specifications are valid only after V_{DD}/V_{DDON} is stable and within the normal operating limits. These parameters are measured from the application of a new signal at REF or FB, or after $\overline{PD}$ is (re)asserted until $t_{(\phi)}$ is within specified limits.
8. The jitter parameters are measured with all outputs selected for 0t_U, FB input divider is set to divide-by-one, and Bit 60 = 1.
9. Both REF inputs must be the same frequency, but up to ±180° out of phase.
10. For HSTL/eHSTL outputs only.
11. For LVTTL outputs only.
12. t_{ODCV} is measured with all outputs selected for zero delay.

AC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

All outputs at the different interface levels

Symbol	Parameter		Min.	Typ.	Max	Unit
F_{NOM}	VCO Frequency Range		see JTAG/I²C Serial Configurations: VCO Frequency Range table			
t_{RPW}	Reference Clock Pulse Width HIGH or LOW		1	—	—	ns
t_{FPW}	Feedback Input Pulse Width HIGH or LOW		1	—	—	ns
t_U	Programmable Skew Time Unit		see Control Summary Table			
$t_{SK(O)}$	Output Skew (Rise-Rise, Fall-Fall, Nominal)[1,2]		—	—	250	ps
$t_{SK1(\omega)}$	Multiple Frequency Skew (Rise-Rise, Fall-Fall, Nominal-Divided, Divided-Divided)[1,2,3]		—	—	500	ps
$t_{SK2(\omega)}$	Multiple Frequency Skew (Rise-Fall, Nominal-Divided, Divided-Divided)[1,2,3]		—	—	500	ps
$t_{SK1(INV)}$	Inverting Skew (Nominal-Inverted)[1,2]		—	—	500	ps
$t_{SK2(INV)}$	Inverting Skew (Rise-Rise, Fall-Fall, Rise-Fall, Inverted-Divided)[1,2,3]		—	—	500	ps
$t_{SK(PR)}$	Process Skew[1,2,4]		—	—	400	ps
$t_{(\phi)}$	REF Input to FB Static Phase Offset[5]		-200	—	200	ps
t_{ODCV}	Output Duty Cycle Variation from 50%[11,12]	1.8V LVTTL	-475	—	475	ps
		2.5V LVTTL	-375	—	375	
t_{ORISE}	Output Rise Time[6]	HSTL / eHSTL / 1.8V LVTTL	—	—	1.2	ns
		2.5V LVTTL	—	—	1	
t_{OFALL}	Output Fall Time[6]	HSTL / eHSTL / 1.8V LVTTL	—	—	1.2	ns
		2.5V LVTTL	—	—	1	
t_L	Power-up PLL Lock Time[7]		—	—	4	ms
$t_{L(\omega)}$	PLL Lock Time After Input Frequency Change[7]		—	—	1	ms
$t_{L(PD)}$	PLL Lock Time After Asserting $\overline{PD}$ Pin[7]		—	—	1	ms
$t_{L(REFSEL1)}$	PLL Lock Time After Change in REF_SEL[7,9]		—	—	100	μs
$t_{L(REFSEL2)}$	PLL Lock Time After Change in REF_SEL (REF1 and REF0 are different frequency)[7]		—	—	1	ms
$t_{JIT(CC)}$	Cycle-to-Cycle Output Jitter (peak-to-peak)[2,8]		—	—	100	ps
$t_{JIT(PER)}$	Period Jitter (peak-to-peak)[2,8]		—	—	150	ps
$t_{JIT(HP)}$	Half Period Jitter (peak-to-peak)[2,8,10]		—	—	200	ps
$t_{JIT(DUTY)}$	Duty Cycle Jitter (peak-to-peak)[2,8]		—	—	150	ps
V_{OX}	HSTL and eHSTL Differential True and Complementary Output Crossing Voltage Level		$V_{DDQN}/2 - 150$	$V_{DDQN}/2$	$V_{DDQN}/2 + 150$	mV

NOTES:

1. Skew is the time between the earliest and latest output transition among all outputs for which the same t_U delay has been selected, when all outputs are loaded with the specified load.
2. For differential LVTTL outputs, the measurement is made at $V_{DDQN}/2$, where the true outputs are only compared with other true outputs and the complementary outputs are only compared to other complementary outputs. For differential HSTL/eHSTL outputs, the measurement is made at the crossing point (V_{OX}) of the true and complementary signals.
3. There are three classes of outputs: nominal (multiple of t_U delay), inverted, and divided (divide-by-2 or divide-by-4 mode).
4. $t_{SK(PR)}$ is the output to corresponding output skew between any two devices operating under the same conditions (V_{DD} and V_{DDQN}, ambient temperature, air flow, etc.).
5. $t_{(\phi)}$ is measured with REF and FB the same type of input, the same rise and fall times. For 1.8V / 2.5V LVTTL input and output, the measurement is taken from V_{THI} on REF to V_{THI} on FB. For HSTL / eHSTL input and output, the measurement is taken from the crosspoint of REF/$\overline{REF}$ to the crosspoint of FB/$\overline{FB}$. All outputs are set to 0t_U, FB input divider is set to divide-by-one, and Bit 60 = 1.
6. Output rise and fall times are measured between 20% to 80% of the actual output voltage swing.
7. t_L, $t_{L(\omega)}$, $t_{L(REFSEL1)}$, $t_{L(REFSEL2)}$, and $t_{L(PD)}$ are the times that are required before the synchronization is achieved. These specifications are valid only after V_{DD}/V_{DDQN} is stable and within the normal operating limits. These parameters are measured from the application of a new signal at REF or FB, or after $\overline{PD}$ is (re)asserted until $t_{(\phi)}$ is within specified limits.
8. The jitter parameters are measured with all outputs selected for 0t_U, FB input divider is set to divide-by-one, and Bit 60 = 1.
9. Both REF inputs must be the same frequency, but up to ±180° out of phase.
10. For HSTL/eHSTL outputs only.
11. For LVTTL outputs only.
12. t_{ODCV} is measured with all outputs selected for zero delay.

AC DIFFERENTIAL INPUT SPECIFICATIONS[(1)]

Symbol	Parameter	Min.	Typ.	Max	Unit
t_W	Reference/Feedback Input Clock Pulse Width HIGH or LOW (HSTL/eHSTL outputs)[(2)]	1	—	—	ns
	Reference/Feedback Input Clock Pulse Width HIGH or LOW (2.5V / 1.8V LVTTL outputs)[(2)]	1	—	—	

HSTL/eHSTL/1.8V LVTTL/2.5V LVTTL

Symbol	Parameter	Min.	Typ.	Max	Unit
V_{DIF}	AC Differential Voltage[(3)]	400	—	—	mV
V_{IH}	AC Input HIGH[(4,5)]	Vx + 200	—	—	mV
V_{IL}	AC Input LOW[(4,6)]	—	—	Vx - 200	mV

LVEPECL

Symbol	Parameter	Min.	Typ.	Max	Unit
V_{DIF}	AC Differential Voltage[(3)]	400	—	—	mV
V_{IH}	AC Input HIGH[(4)]	1275	—	—	mV
V_{IL}	AC Input LOW[(4)]	—	—	875	mV

NOTES:

1. For differential input mode, Bits 35 - 30 = 1.

2. Both differential input signals should not be driven to the same level simultaneously. The input will not change state until the inputs have crossed and the voltage range defined by V_{DIF} has been met or exceeded.

3. Differential mode only. V_{DIF} specifies the minimum input voltage (V_{TR} - V_{CP}) required for switching where V_{TR} is the "true" input level and V_{CP} is the "complement" input level. The AC differential voltage must be achieved to guarantee switching to a new state.

4. For single-ended operation, $\overline{REF}_{[1:0]}$/$V_{REF[1:0]}$ is tied to the DC voltage $V_{REF[1:0]}$. Refer to each input interface's DC specification for the correct $V_{REF[1:0]}$ range.

5. Voltage required to switch to a logic HIGH, single-ended operation only.

6. Voltage required to switch to a logic LOW, single-ended operation only.
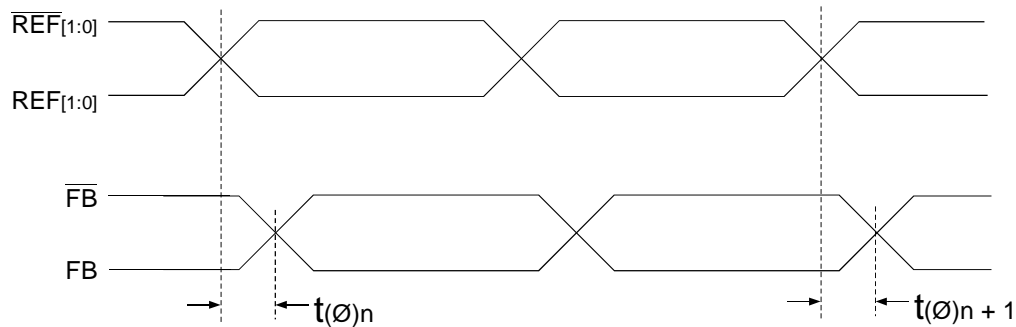
AC TIMING DIAGRAM[1]
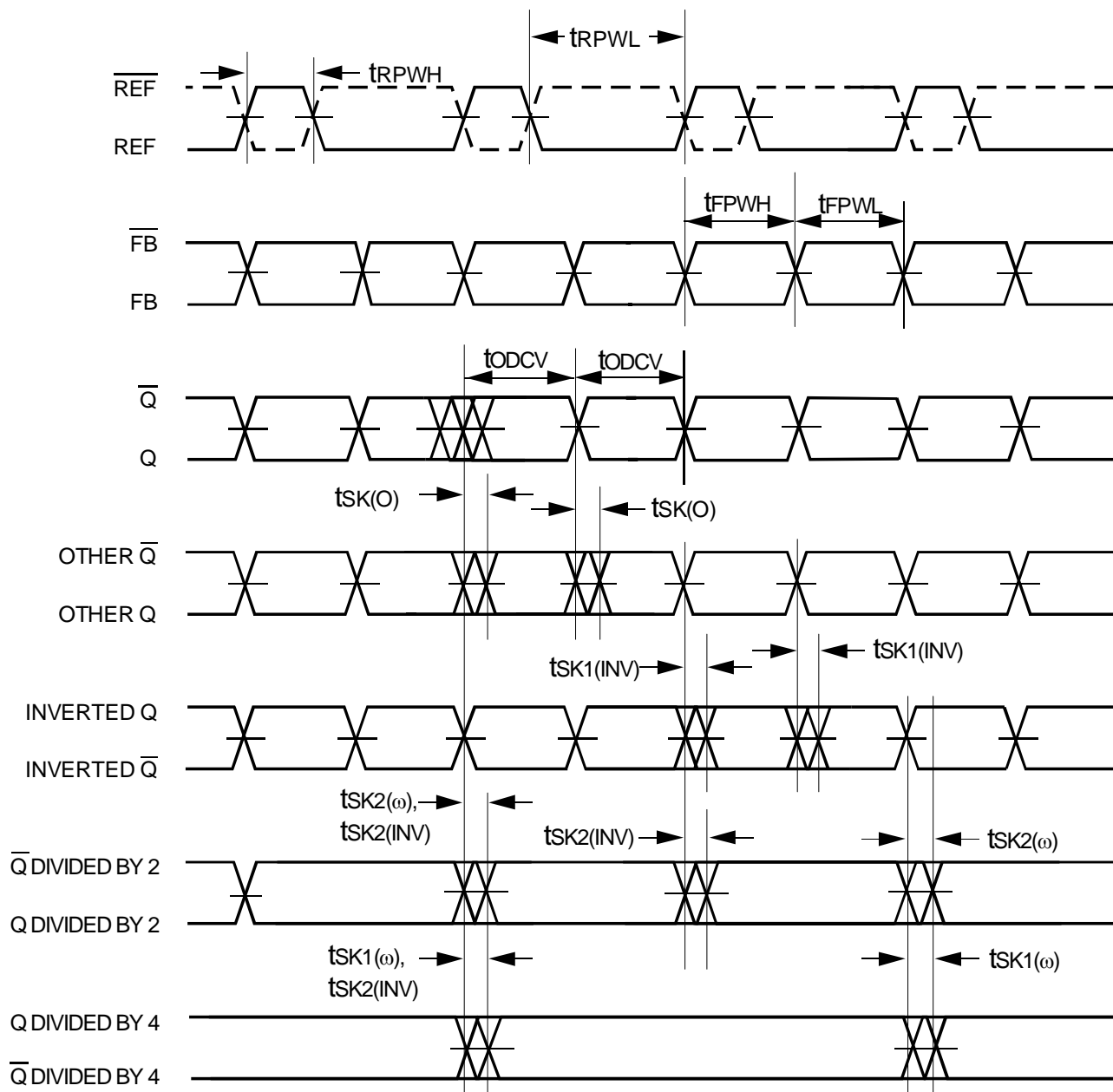
NOTE:
1. The AC TIMING DIAGRAM applies to Bit 58 = 1. For Bit 58 = 0, the negative edge of FB aligns with the negative edge of $REF_{[1:0]}$, divided outputs change on the negative edge of $REF_{[1:0]}$, and the positive edges of the divide-by-2 and divide-by-4 signals align.

JITTER AND OFFSET TIMING WAVEFORMS
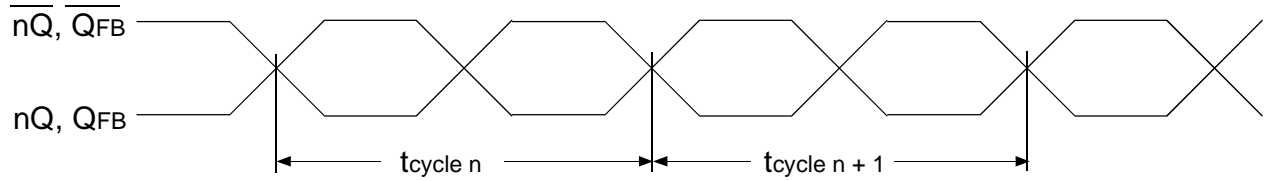
$$t_{jit(cc)} = t_{cycle\ n} - t_{cycle\ n+1}$$
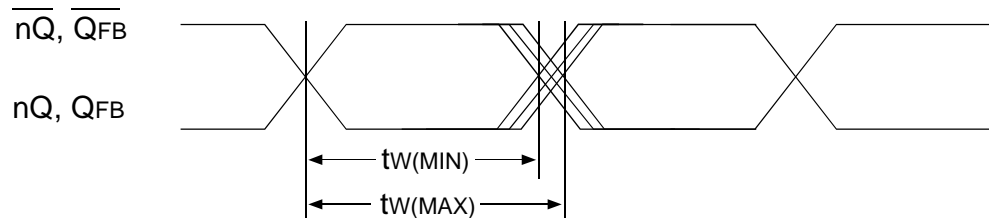
Cycle-to-Cycle jitter

$$t_{(\varnothing)} = \dfrac{\displaystyle\sum_{1}^{n=N} t_{(\varnothing)n}}{N}$$
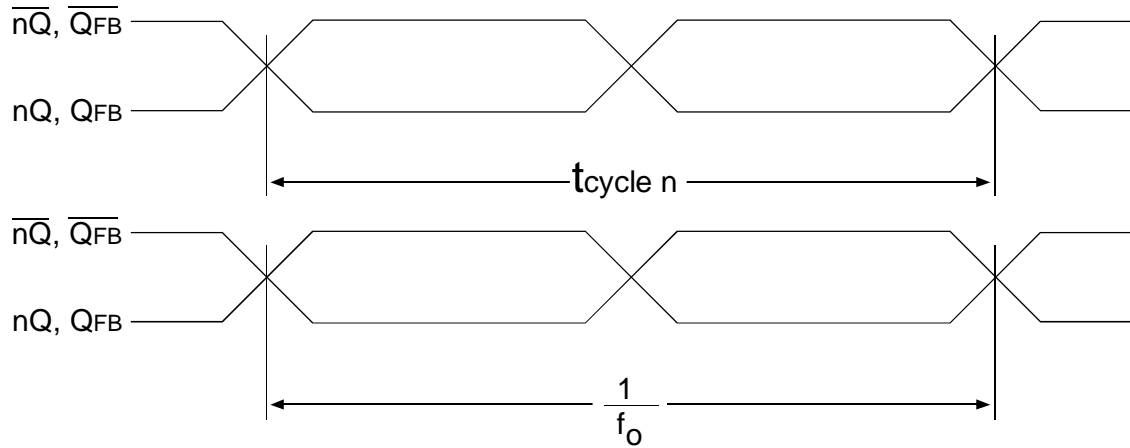
(N is a large number of samples)

Static Phase Offset

NOTE:
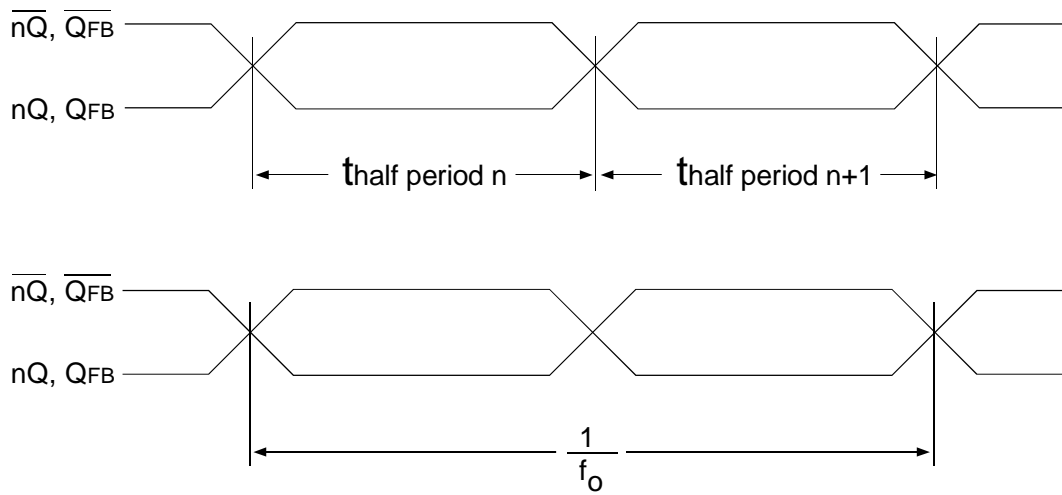1. Diagram for Bit 58 = 1 and HSTL / eHSTL input and output.

$$t_{JIT(DUTY)} = \left| t_{W(MAX)} - t_{W(MIN)} \right|$$

Duty-Cycle Jitter

$\overline{nQ}, \overline{Q_{FB}}$

nQ, Q_{FB}

$t_{cycle\ n}$

$\overline{nQ}, \overline{Q_{FB}}$

nQ, Q_{FB}

$\dfrac{1}{f_O}$

$$t_{jit(per)} = t_{cycle\ n} - \frac{1}{f_O}$$

Period jitter

$\overline{nQ}, \overline{Q_{FB}}$

nQ, Q_{FB}

$t_{half\ period\ n}$ $t_{half\ period\ n+1}$

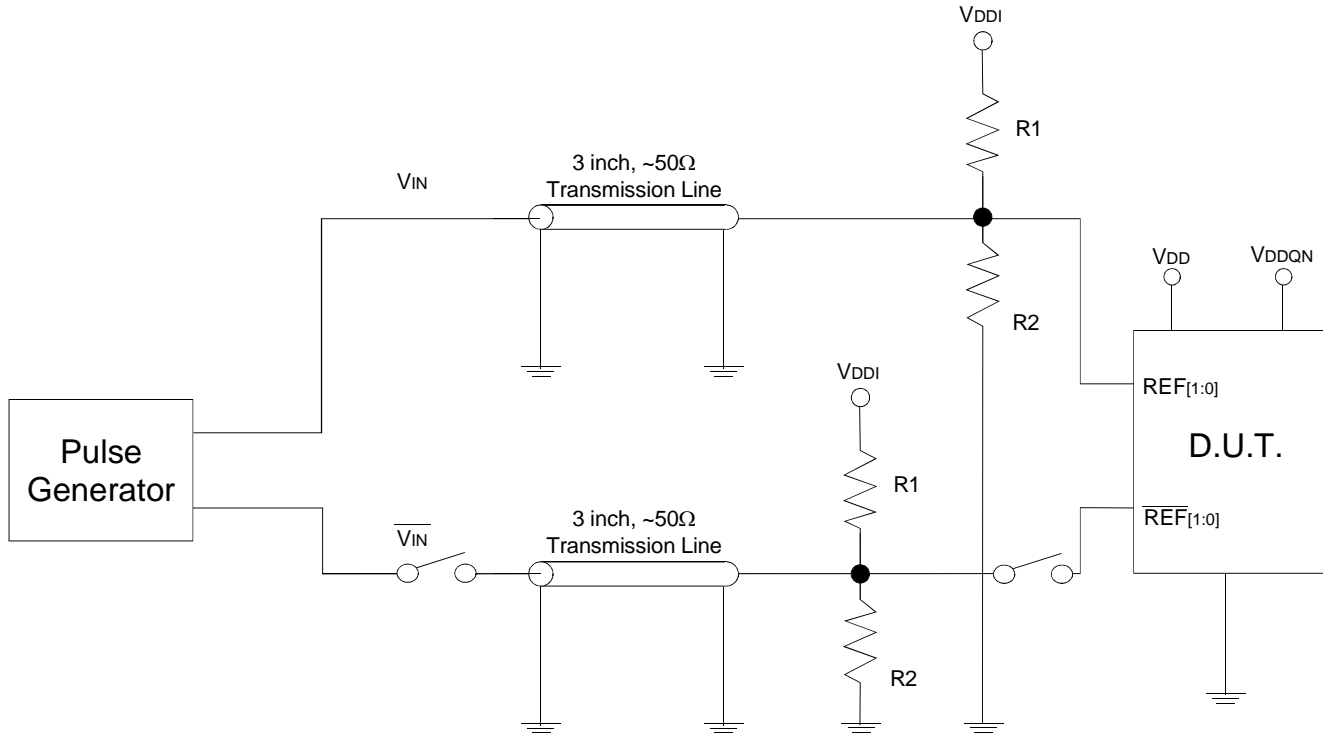$\overline{nQ}, \overline{Q_{FB}}$

nQ, Q_{FB}

$\dfrac{1}{f_O}$

$$t_{jit(hper)} = t_{half\ period\ n} - \frac{1}{2*f_O}$$

Half-Period jitter

TEST CIRCUITS AND CONDITIONS

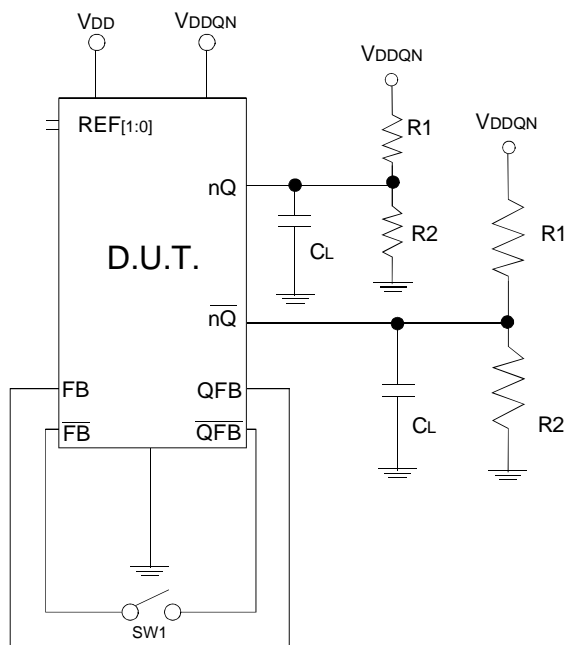*Test Circuit for Differential Input[1]*

DIFFERENTIAL INPUT TEST CONDITIONS

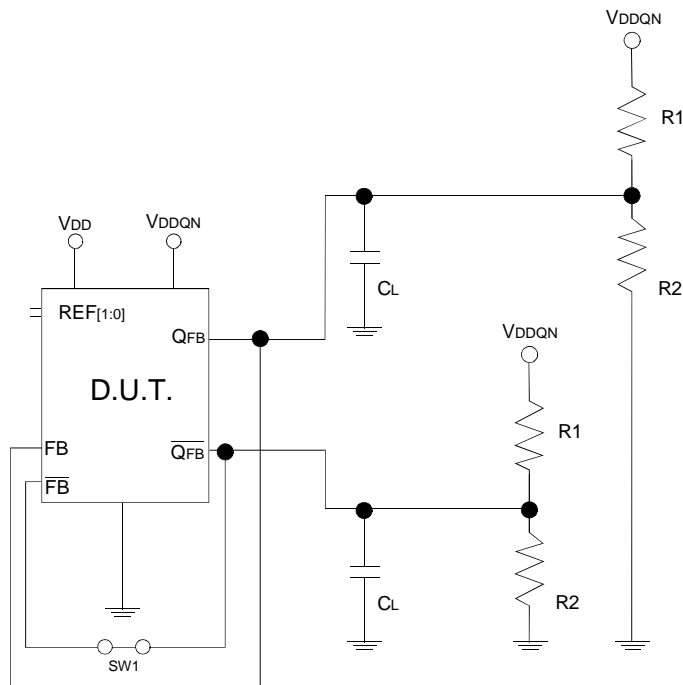| Symbol	$V_{DD} = 2.5V \pm 0.2V$	Unit
R1	100	Ω
R2	100	Ω
V_{DDI}	$V_{CM}*2$	V
V_{THI}	HSTL: Crossing of REF[1:0] and $\overline{REF}$[1:0] eHSTL: Crossing of REF[1:0] and $\overline{REF}$[1:0] LVEPECL: Crossing of REF[1:0] and $\overline{REF}$[1:0] 1.8V LVTTL: $V_{DDI}/2$ 2.5V LVTTL: $V_{DD}/2$	V

NOTE:

1. This input configuration is used for all input interfaces. For single-ended testing, the $\overline{REF}$[1:0] must be left floating. For testing single-ended in differential input mode, the $\overline{V_{IN}}$ should be floating.
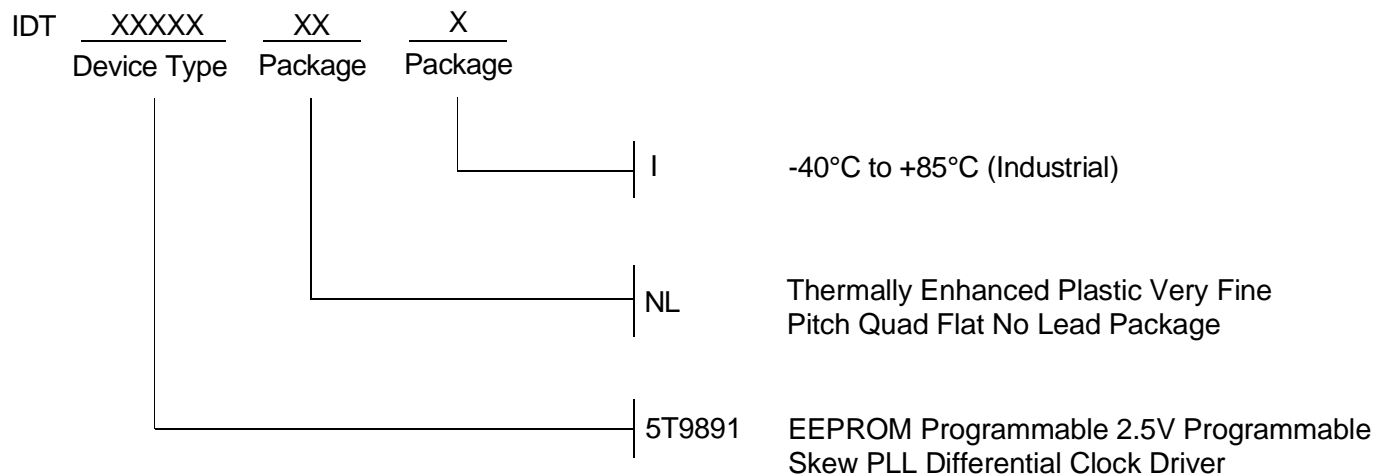
Test Circuit for Differential Outputs

Test Circuit for Differential Feedback

DIFFERENTIAL OUTPUT TEST CONDITIONS

Symbol	$V_{DD} = 2.5V \pm 0.2V$ $V_{DDQN} =$ **Interface Specified**	Unit
C_L	15	pF
R1	100	Ω
R2	100	Ω
V_{OX}	HSTL: Crossing of nQ and $\overline{nQ}$	V
	eHSTL: Crossing of nQ and $\overline{nQ}$	
V_{THO}	1.8V LVTTL: $V_{DDQN}/2$	V
	2.5V LVTTL: $V_{DDQN}/2$	
SW1	1.8V/2.5V LVTTL	Open
	HSTL/eHSTL	Closed

DIFFERENTIAL FEEDBACK TEST CONDITIONS

Symbol	$V_{DD} = 2.5V \pm 0.2V$ $V_{DDQN} =$ **Interface Specified**	Unit
C_L	15	pF
R1	100	Ω
R2	100	Ω
V_{OX}	HSTL: Crossing of Q_{FB} and $\overline{Q_{FB}}$	V
	eHSTL: Crossing of Q_{FB} and $\overline{Q_{FB}}$	
V_{THO}	1.8V LVTTL: $V_{DDQN}/2$	V
	2.5V LVTTL: $V_{DDQN}/2$	
SW1	1.8V/2.5V LVTTL	Open
	HSTL/eHSTL	Closed

ORDERING INFORMATION

IDT   <u>XXXXX</u>   <u>XX</u>   <u>X</u>
      Device Type   Package   Package

I   -40°C to +85°C (Industrial)

NL   Thermally Enhanced Plastic Very Fine
        Pitch Quad Flat No Lead Package

5T9891   EEPROM Programmable 2.5V Programmable
          Skew PLL Differential Clock Driver

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